

# **DDR3L SDRAM Unbuffered SODIMMs Based on 4Gb A-die**

**HMT425S6AFR6A  
HMT451S6AFR6A  
HMT451S6AFR8A  
HMT41GS6AFR8A**

**\*SK hynix reserves the right to change products or specifications without notice.**

## Revision History

| Revision No. | History                                                         | Draft Date | Remark |
|--------------|-----------------------------------------------------------------|------------|--------|
| 0.1          | Initial Release                                                 | Jul. 2012  |        |
| 1.0          | Change module maximum thickness to reflect the measured maximum | Jul.2013   |        |
| 1.1          | Added 1866Mbps specification                                    | Aug.2013   |        |

## Description

SK hynix Unbuffered Small Outline DDR3L SDRAM DIMMs (Unbuffered Small Outline Double Data Rate Synchronous DRAM Dual In-Line Memory Modules) are low power, high-speed operation memory modules that use DDR3L SDRAM devices. These Unbuffered DDR3L SDRAM SODIMMs are intended for use as main memory when installed in systems such as mobile personal computers.

## Features

- Power Supply: VDD=1.35V (1.283V to 1.45V)
- VDDQ = 1.35V (1.283V to 1.45V)
- VDDSPD=3.0V to 3.6V
- Backward Compatible with 1.5V DDR3 Memory module
- 8 internal banks
- Data transfer rates: PC3-14900, PC3-12800, PC3-10600, PC3-8500
- Bi-directional Differential Data Strobe
- 8 bit pre-fetch
- Burst Length (BL) switch on-the-fly: BL 8 or BC (Burst Chop) 4
- On Die Termination (ODT) supported
- This product is in Compliance with the RoHS directive

## Ordering Information

| Part Number               | Density | Organization | Component Composition  | # of ranks |
|---------------------------|---------|--------------|------------------------|------------|
| HMT425S6AFR6A-G7/H9/PB/RD | 2GB     | 256Mx64      | 256Mx16(H5TC4G63AFR)*4 | 1          |
| HMT451S6AFR6A-G7/H9/PB/RD | 4GB     | 512Mx64      | 256Mx16(H5TC4G63AFR)*8 | 2          |
| HMT451S6AFR8A-G7/H9/PB/RD | 4GB     | 512Mx64      | 512Mx8(H5TC4G83AFR)*8  | 1          |
| HMT41GS6AFR8A-G7/H9/PB/RD | 8GB     | 1Gx64        | 512Mx8(H5TC4G83AFR)*16 | 2          |

## Key Parameters

| MT/s              | Grade | tCK (ns) | CAS Latency (tCK) | tRCD (ns)          | tRP (ns)           | tRAS (ns) | tRC (ns)           | CL-tRCD-tRP |
|-------------------|-------|----------|-------------------|--------------------|--------------------|-----------|--------------------|-------------|
| <b>DDR3L-1066</b> | -G7   | 1.875    | 7                 | 13.125             | 13.125             | 37.5      | 50.625             | 7-7-7       |
| <b>DDR3L-1333</b> | -H9   | 1.5      | 9                 | 13.5<br>(13.125)*  | 13.5<br>(13.125)*  | 36        | 49.5<br>(49.125)*  | 9-9-9       |
| <b>DDR3L-1600</b> | -PB   | 1.25     | 11                | 13.75<br>(13.125)* | 13.75<br>(13.125)* | 35        | 48.75<br>(48.125)* | 11-11-11    |
| <b>DDR3L-1866</b> | -RD   | 1.07     | 13                | 13.91<br>(13.125)* | 13.91<br>(13.125)* | 34        | 47.91<br>(47.125)* | 13-13-13    |

\*SK hynix DRAM devices support optional downbinning to CL11, CL9 and CL7. SPD setting is programmed to match.

## Speed Grade

| Grade | Frequency [MHz] |     |      |      |      |      |      |      |      | Remark |
|-------|-----------------|-----|------|------|------|------|------|------|------|--------|
|       | CL5             | CL6 | CL7  | CL8  | CL9  | CL10 | CL11 | CL12 | CL13 |        |
| -G7   | 667             | 800 | 1066 | 1066 |      |      |      |      |      |        |
| -H9   | 667             | 800 | 1066 | 1066 | 1333 | 1333 |      |      |      |        |
| -PB   | 667             | 800 | 1066 | 1066 | 1333 | 1333 | 1600 |      |      |        |
| -RD   |                 | 800 | 1066 | 1066 | 1333 | 1333 | 1600 |      | 1866 |        |

## Address Table

|                       | 2GB(1Rx16) | 4GB(2Rx16) | 4GB(1Rx8) | 8GB(2Rx8) |
|-----------------------|------------|------------|-----------|-----------|
| <b>Refresh Method</b> | 8K/64ms    | 8K/64ms    | 8K/64ms   | 8K/64ms   |
| <b>Row Address</b>    | A0-A14     | A0-A14     | A0-A15    | A0-A15    |
| <b>Column Address</b> | A0-A9      | A0-A9      | A0-A9     | A0-A9     |
| <b>Bank Address</b>   | BA0-BA2    | BA0-BA2    | BA0-BA2   | BA0-BA2   |
| <b>Page Size</b>      | 2KB        | 2KB        | 1KB       | 1KB       |

## Pin Descriptions

| Pin Name                     | Description                              | Number | Pin Name                      | Description                                             | Number     |
|------------------------------|------------------------------------------|--------|-------------------------------|---------------------------------------------------------|------------|
| CK[1:0]                      | Clock Input, positive line               | 2      | DQ[63:0]                      | Data Input/Output                                       | 64         |
| $\overline{\text{CK}}$ [1:0] | Clock Input, negative line               | 2      | DM[7:0]                       | Data Masks                                              | 8          |
| CKE[1:0]                     | Clock Enables                            | 2      | DQS[7:0]                      | Data strobes                                            | 8          |
| $\overline{\text{RAS}}$      | Row Address Strobe                       | 1      | $\overline{\text{DQS}}$ [7:0] | Data strobes, negative line                             | 8          |
| $\overline{\text{CAS}}$      | Column Address Strobe                    | 1      | $\overline{\text{EVENT}}$     | Temperature event pin                                   | 1          |
| $\overline{\text{WE}}$       | Write Enable                             | 1      | TEST                          | Logic Analyzer specific test pin (No connect on SODIMM) | 1          |
| $\overline{\text{S}}$ [1:0]  | Chip Selects                             | 2      | $\overline{\text{RESET}}$     | Reset Pin                                               | 1          |
| A[9:0], A11, A[15:13]        | Address Inputs                           | 14     | V <sub>DD</sub>               | Core and I/O Power                                      | 18         |
| A10/AP                       | Address Input/Autoprecharge              | 1      | V <sub>SS</sub>               | Ground                                                  | 52         |
| A12/ $\overline{\text{BC}}$  | Address Input/Burst chop                 | 1      |                               |                                                         |            |
| BA[2:0]                      | SDRAM Bank Addresses                     | 3      | V <sub>REFDQ</sub>            | Input/Output Reference                                  | 1          |
| ODT[1:0]                     | On Die Termination Inputs                | 2      | V <sub>REFCA</sub>            |                                                         | 1          |
| SCL                          | Serial Presence Detect (SPD) Clock Input | 1      | V <sub>TT</sub>               | Termination Voltage                                     | 2          |
| SDA                          | SPD Data Input/Output                    | 1      | V <sub>DDSPD</sub>            | SPD Power                                               | 1          |
| SA[1:0]                      | SPD Address Inputs                       | 2      | NC                            | Reserved for future use                                 | 2          |
|                              |                                          |        |                               | <b>Total:</b>                                           | <b>204</b> |

## Input/Output Functional Descriptions

| Symbol                                                             | Type   | Polarity    | Function                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                        |
|--------------------------------------------------------------------|--------|-------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| $\overline{CK0}/\overline{CK0}$<br>$\overline{CK1}/\overline{CK1}$ | IN     | Cross Point | The system clock inputs. All address and command lines are sampled on the cross point of the rising edge of CK and falling edge of $\overline{CK}$ . A Delay Locked Loop (DLL) circuit is driven from the clock inputs and output timing for read operations is synchronized to the input clock.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                |
| CKE[1:0]                                                           | IN     | Active High | Activates the DDR3L SDRAM CK signal when high and deactivates the CK signal when low. By deactivating the clocks, CKE low initiates the Power Down mode or the Self Refresh mode.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                               |
| $\overline{S}[1:0]$                                                | IN     | Active Low  | Enables the associated DDR3L SDRAM command decoder when low and disables the command decoder when high. When the command decoder is disabled, new commands are ignored but previous operations continue. Rank 0 is selected by $\overline{S0}$ ; Rank 1 is selected by $\overline{S1}$ .                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                        |
| ODT[1:0]                                                           | IN     | Active High | Asserts on-die termination for DQ, DM, DQS, and $\overline{DQS}$ signals if enabled via the DDR3L SDRAM mode register.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                          |
| $\overline{RAS}$ , $\overline{CAS}$ , $\overline{WE}$              | IN     | Active Low  | When sampled at the cross point of the rising edge of CK, signals $\overline{CAS}$ , $\overline{RAS}$ , and $\overline{WE}$ define the operation to be executed by the SDRAM.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                   |
| $V_{REFDQ}$<br>$V_{REFCA}$                                         | Supply |             | Reference voltage for SSTL15 inputs.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                            |
| BA[2:0]                                                            | IN     | —           | Selects which SDRAM internal bank of eight is activated.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                        |
| A[9:0],<br>A10/AP,<br>A11,<br>A12/ $\overline{BC}$<br>A[15:13]     | IN     | —           | During a Bank Activate command cycle, defines the row address when sampled at the cross point of the rising edge of CK and falling edge of CK. During a Read or Write command cycle, defines the column address when sampled at the cross point of the rising edge of CK and falling edge of $\overline{CK}$ . In addition to the column address, AP is used to invoke autoprecharge operation at the end of the burst read or write cycle. If AP is high autoprecharge is selected and BA0-BAn defines the bank to be precharged. If AP is low, autoprecharge is disabled. During a Precharge command cycle, AP is used in conjunction with BA0-BAn to control which bank(s) to precharge. If AP is high, all banks will be precharged regardless of the state of BA0-BAn inputs. If AP is low, then BA0-BAn are used to define which bank to precharge. A12( $\overline{BC}$ ) is samples during READ and WRITE commands to determine if burst chop (on-the-fly) will be performed (HIGH, no burst chop: LOW, burst chopped). |
| DQ[63:0]                                                           | I/O    | —           | Data Input/Output pins.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                         |
| DM[7:0]                                                            | IN     | Active High | The data write masks, associated with one data byte. In Write mode, DM operates as a byte mask by allowing input data to be written if it is low but blocks the write operation if it is high. In Read mode, DM lines have no effect.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                           |
| $V_{DD}$ , $V_{DDSPD}$<br>$V_{SS}$                                 | Supply |             | Power supplies for core, I/O, Serial Presence Detect, and ground for the module.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                |
| $\overline{DQS}[7:0]$ ,<br>$\overline{DQS}[7:0]$                   | I/O    | Cross Point | The data strobes, associated with one data byte, sourced with data transfers. In Write mode, the data strobe is sourced by the controller and is centered in the data window. In Read mode, the data strobe is sourced by the DDR3L SDRAMs and is sent at the leading edge of the data window. $\overline{DQS}$ signals are complements, and timing is relative to the crosspoint of respective DQS and $\overline{DQS}$ .                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                      |
| SA[1:0]                                                            | IN     | —           | These signals are tied at the system planar to either $V_{SS}$ or $V_{DDSPD}$ to configure the serial SPD EEPROM address range.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                 |

| Symbol                    | Type                | Polarity   | Function                                                                                                                                                                                                                                                          |
|---------------------------|---------------------|------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| SDA                       | I/O                 | —          | This bidirectional pin is used to transfer data into or out of the SPD EEPROM. A resistor must be connected from the SDA bus line to $V_{DDSPD}$ on the system planar to act as a pullup.                                                                         |
| SCL                       | IN                  | —          | This signal is used to clock data into and out of the SPD EEPROM. A resistor may be connected from the SCL bus time to $V_{DDSPD}$ on the system planar to act as a pullup.                                                                                       |
| $\overline{\text{EVENT}}$ | OUT<br>(open drain) | Active Low | This signal indicates that a thermal event has been detected in the thermal sensing device. The system should guarantee the electrical level requirement is met for the $\overline{\text{EVENT}}$ pin on TS/SPD part.<br>No pull-up resistor is provided on DIMM. |
| $V_{DDSPD}$               | Supply              |            | Serial EEPROM positive power supply wired to a separate power pin at the connector which supports from 3.0 Volt to 3.6 Volt (nominal 3.3V) operation.                                                                                                             |
| $\overline{\text{RESET}}$ | IN                  |            | The $\overline{\text{RESET}}$ pin is connected to the $\overline{\text{RESET}}$ pin on the register and to the $\overline{\text{RESET}}$ pin on the DRAM.                                                                                                         |
| TEST                      |                     |            | Used by memory bus analysis tools (unused (NC) on memory DIMMs)                                                                                                                                                                                                   |

## Pin Assignments

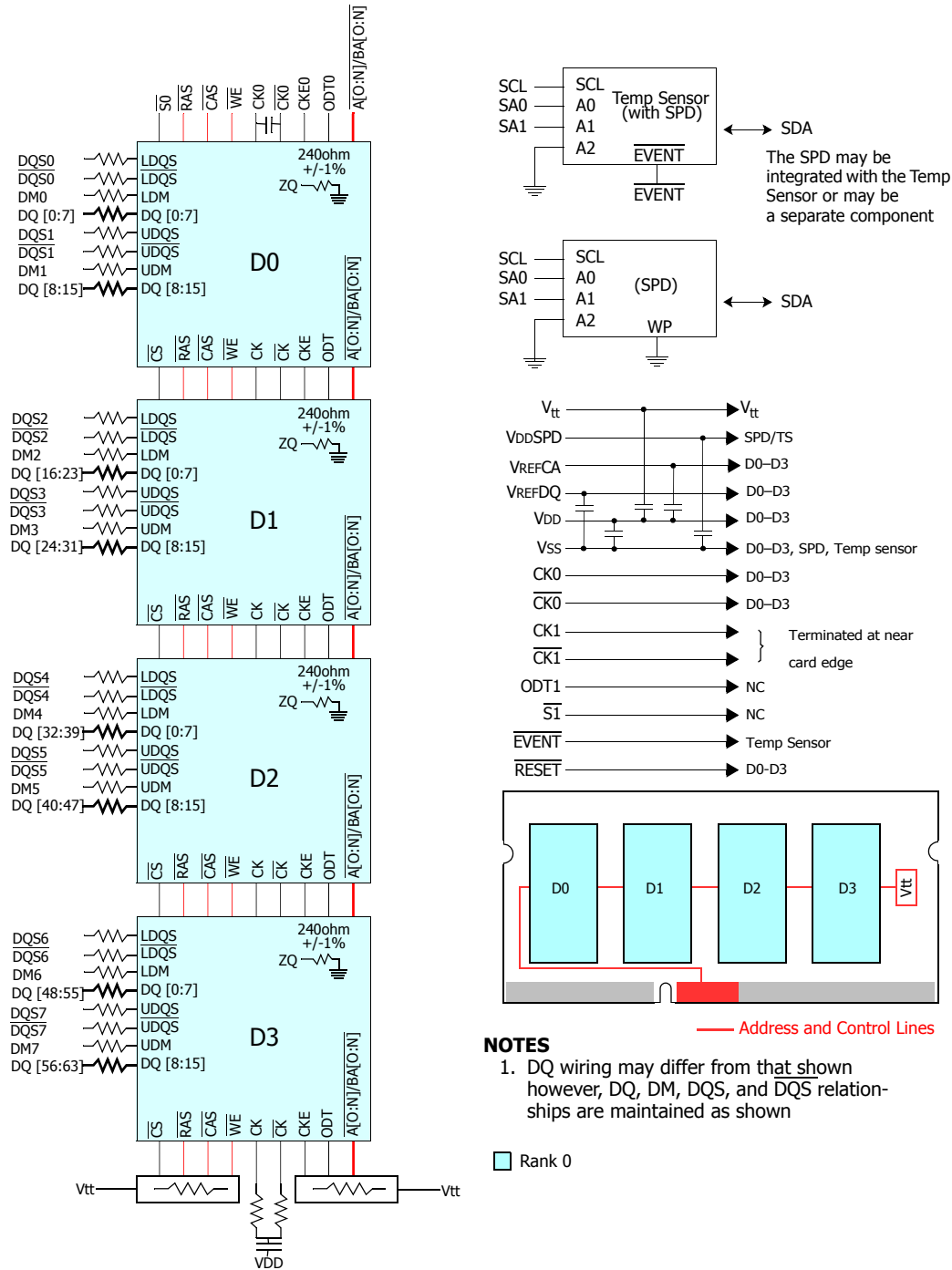
| Pin # | Front Side               | Pin # | Back Side                 | Pin # | Front Side                  | Pin # | Back Side                | Pin # | Front Side               | Pin # | Back Side                | Pin # | Front Side               | Pin # | Back Side                 |
|-------|--------------------------|-------|---------------------------|-------|-----------------------------|-------|--------------------------|-------|--------------------------|-------|--------------------------|-------|--------------------------|-------|---------------------------|
| 1     | V <sub>REF</sub> DQ      | 2     | V <sub>SS</sub>           | 53    | DQ19                        | 54    | V <sub>SS</sub>          | 105   | V <sub>DD</sub>          | 106   | V <sub>DD</sub>          | 157   | DQ42                     | 158   | DQ46                      |
| 3     | V <sub>SS</sub>          | 4     | DQ4                       | 55    | V <sub>SS</sub>             | 56    | DQ28                     | 107   | A10/AP                   | 108   | BA1                      | 159   | DQ43                     | 160   | DQ47                      |
| 5     | DQ0                      | 6     | DQ5                       | 57    | DQ24                        | 58    | DQ29                     | 109   | BA0                      | 110   | $\overline{\text{RAS}}$  | 161   | V <sub>SS</sub>          | 162   | V <sub>SS</sub>           |
| 7     | DQ1                      | 8     | V <sub>SS</sub>           | 59    | DQ25                        | 60    | V <sub>SS</sub>          | 111   | V <sub>DD</sub>          | 112   | V <sub>DD</sub>          | 163   | DQ48                     | 164   | DQ52                      |
| 9     | V <sub>SS</sub>          | 10    | $\overline{\text{DQS0}}$  | 61    | V <sub>SS</sub>             | 62    | $\overline{\text{DQS3}}$ | 113   | $\overline{\text{WE}}$   | 114   | $\overline{\text{S0}}$   | 165   | DQ49                     | 166   | DQ53                      |
| 11    | DM0                      | 12    | DQS0                      | 63    | DM3                         | 64    | DQS3                     | 115   | $\overline{\text{CAS}}$  | 116   | ODT0                     | 167   | V <sub>SS</sub>          | 168   | V <sub>SS</sub>           |
| 13    | V <sub>SS</sub>          | 14    | V <sub>SS</sub>           | 65    | V <sub>SS</sub>             | 66    | V <sub>SS</sub>          | 117   | V <sub>DD</sub>          | 118   | V <sub>DD</sub>          | 169   | $\overline{\text{DQS6}}$ | 170   | DM6                       |
| 15    | DQ2                      | 16    | DQ6                       | 67    | DQ26                        | 68    | DQ30                     | 119   | A13 <sup>2</sup>         | 120   | ODT1                     | 171   | DQS6                     | 172   | V <sub>SS</sub>           |
| 17    | DQ3                      | 18    | DQ7                       | 69    | DQ27                        | 70    | DQ31                     | 121   | $\overline{\text{S1}}$   | 122   | NC                       | 173   | V <sub>SS</sub>          | 174   | DQ54                      |
| 19    | V <sub>SS</sub>          | 20    | V <sub>SS</sub>           | 71    | V <sub>SS</sub>             | 72    | V <sub>SS</sub>          | 123   | V <sub>DD</sub>          | 124   | V <sub>DD</sub>          | 175   | DQ50                     | 176   | DQ55                      |
| 21    | DQ8                      | 22    | DQ12                      | 73    | CKE0                        | 74    | CKE1                     | 125   | TEST                     | 126   | V <sub>REF</sub> CA      | 177   | DQ51                     | 178   | V <sub>SS</sub>           |
| 23    | DQ9                      | 24    | DQ13                      | 75    | V <sub>DD</sub>             | 76    | V <sub>DD</sub>          | 127   | V <sub>SS</sub>          | 128   | V <sub>SS</sub>          | 179   | V <sub>SS</sub>          | 180   | DQ60                      |
| 25    | V <sub>SS</sub>          | 26    | V <sub>SS</sub>           | 77    | NC                          | 78    | A15 <sup>2</sup>         | 129   | DQ32                     | 130   | DQ36                     | 181   | DQ56                     | 182   | DQ61                      |
| 27    | $\overline{\text{DQS1}}$ | 28    | DM1                       | 79    | BA2                         | 80    | A14 <sup>2</sup>         | 131   | DQ33                     | 132   | DQ37                     | 183   | DQ57                     | 184   | V <sub>SS</sub>           |
| 29    | DQS1                     | 30    | $\overline{\text{RESET}}$ | 81    | V <sub>DD</sub>             | 82    | V <sub>DD</sub>          | 133   | V <sub>SS</sub>          | 134   | V <sub>SS</sub>          | 185   | V <sub>SS</sub>          | 186   | $\overline{\text{DQS7}}$  |
| 31    | V <sub>SS</sub>          | 32    | V <sub>SS</sub>           | 83    | A12/ $\overline{\text{BC}}$ | 84    | A11                      | 135   | $\overline{\text{DQS4}}$ | 136   | DM4                      | 187   | DM7                      | 188   | DQS7                      |
| 33    | DQ10                     | 34    | DQ14                      | 85    | A9                          | 86    | A7                       | 137   | DQS4                     | 138   | V <sub>SS</sub>          | 189   | V <sub>SS</sub>          | 190   | V <sub>SS</sub>           |
| 35    | DQ11                     | 36    | DQ15                      | 87    | V <sub>DD</sub>             | 88    | V <sub>DD</sub>          | 139   | V <sub>SS</sub>          | 140   | DQ38                     | 191   | DQ58                     | 192   | DQ62                      |
| 37    | V <sub>SS</sub>          | 38    | V <sub>SS</sub>           | 89    | A8                          | 90    | A6                       | 141   | DQ34                     | 142   | DQ39                     | 193   | DQ59                     | 194   | DQ63                      |
| 39    | DQ16                     | 40    | DQ20                      | 91    | A5                          | 92    | A4                       | 143   | DQ35                     | 144   | V <sub>SS</sub>          | 195   | V <sub>SS</sub>          | 196   | V <sub>SS</sub>           |
| 41    | DQ17                     | 42    | DQ21                      | 93    | V <sub>DD</sub>             | 94    | V <sub>DD</sub>          | 145   | V <sub>SS</sub>          | 146   | DQ44                     | 197   | SA0                      | 198   | $\overline{\text{EVENT}}$ |
| 43    | V <sub>SS</sub>          | 44    | V <sub>SS</sub>           | 95    | A3                          | 96    | A2                       | 147   | DQ40                     | 148   | DQ45                     | 199   | V <sub>DD</sub> SPD      | 200   | SDA                       |
| 45    | $\overline{\text{DQS2}}$ | 46    | DM2                       | 97    | A1                          | 98    | A0                       | 149   | DQ41                     | 150   | V <sub>SS</sub>          | 201   | SA1                      | 202   | SCL                       |
| 47    | DQS2                     | 48    | V <sub>SS</sub>           | 99    | V <sub>DD</sub>             | 100   | V <sub>DD</sub>          | 151   | V <sub>SS</sub>          | 152   | $\overline{\text{DQS5}}$ | 203   | V <sub>TT</sub>          | 204   | V <sub>TT</sub>           |
| 49    | V <sub>SS</sub>          | 50    | DQ22                      | 101   | CK0                         | 102   | CK1                      | 153   | DM5                      | 154   | DQS5                     |       |                          |       |                           |
| 51    | DQ18                     | 52    | DQ23                      | 103   | $\overline{\text{CK0}}$     | 104   | $\overline{\text{CK1}}$  | 155   | V <sub>SS</sub>          | 156   | V <sub>SS</sub>          |       |                          |       |                           |

**NC = No Connect; RFU = Reserved Future Use**

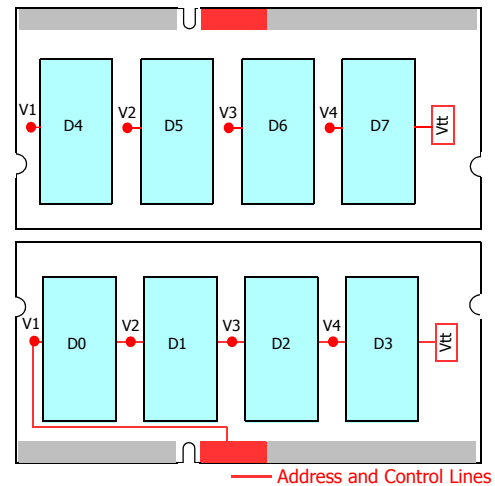
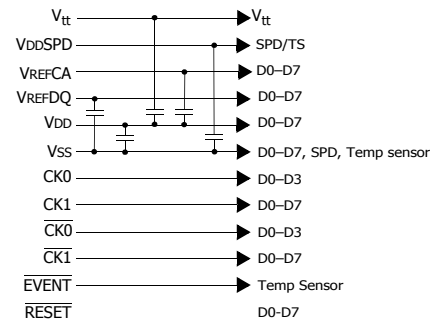
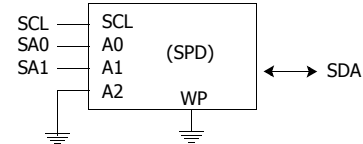
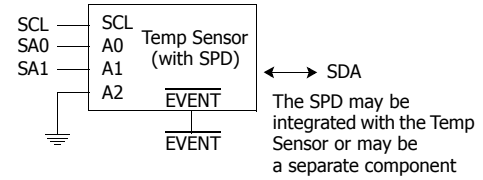
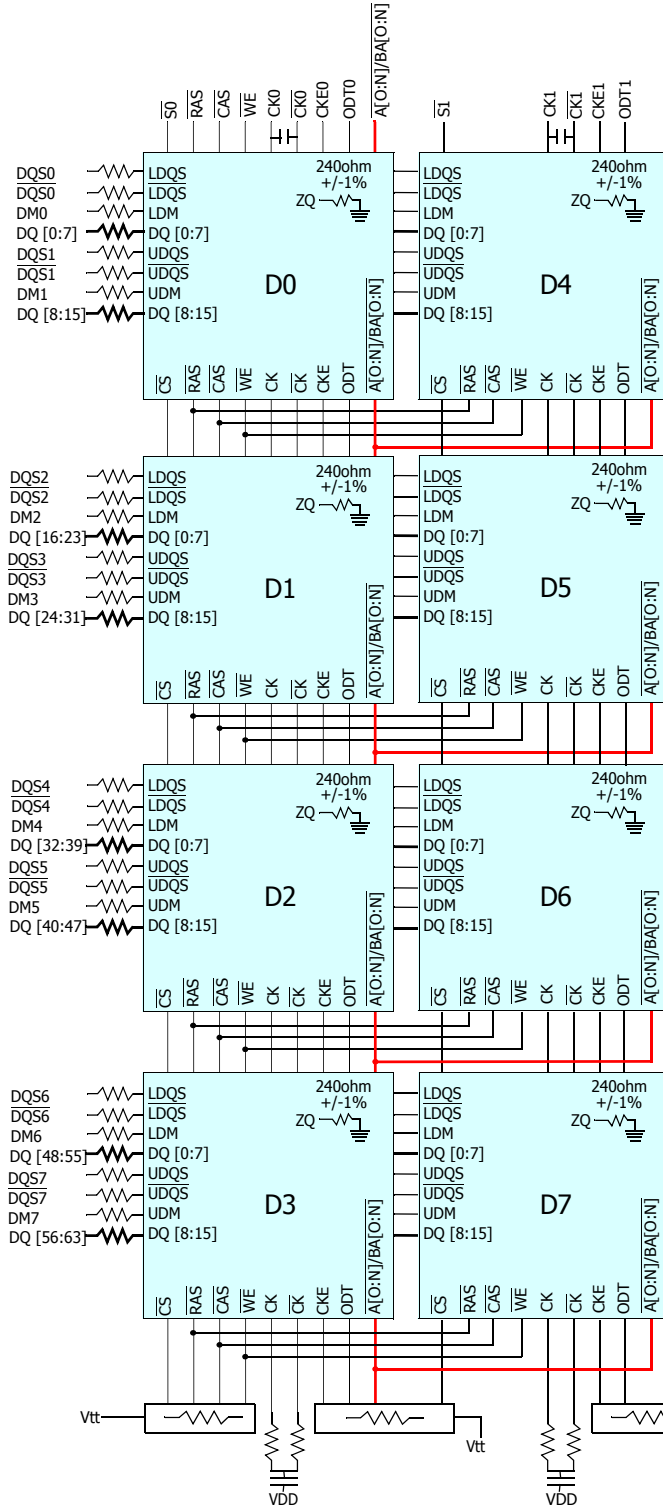
1. TEST (pin 125) is reserved for bus analysis probes and is NC on normal memory modules.
2. This address might be connected to NC balls of the DRAMs (depending on density); either way they will be connected to the termination resistor.

## Functional Block Diagram

### 2GB, 256Mx64 Module(1Rank of x16)



## 4GB, 512Mx64 Module(2Rank of x16)

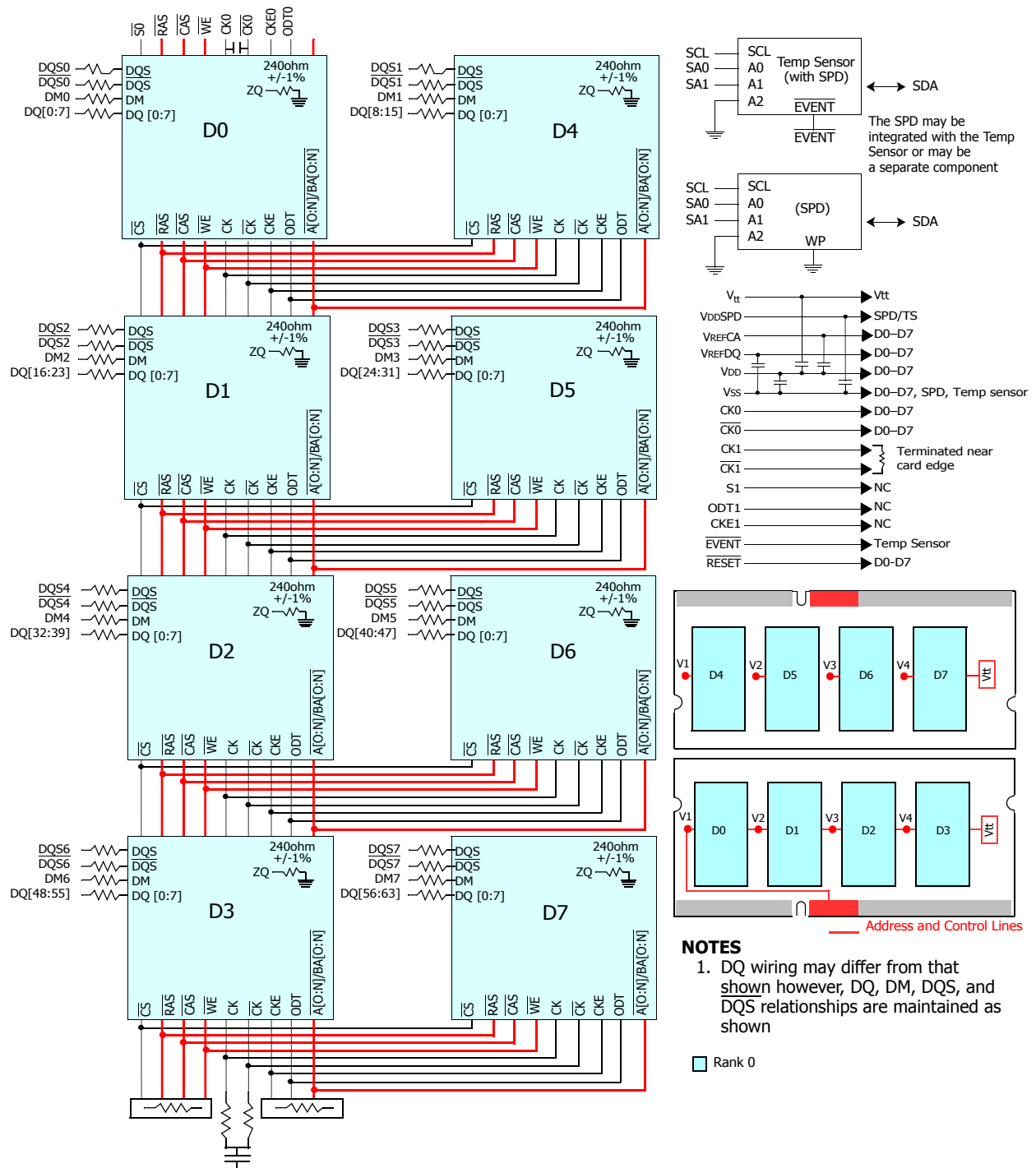


### NOTES

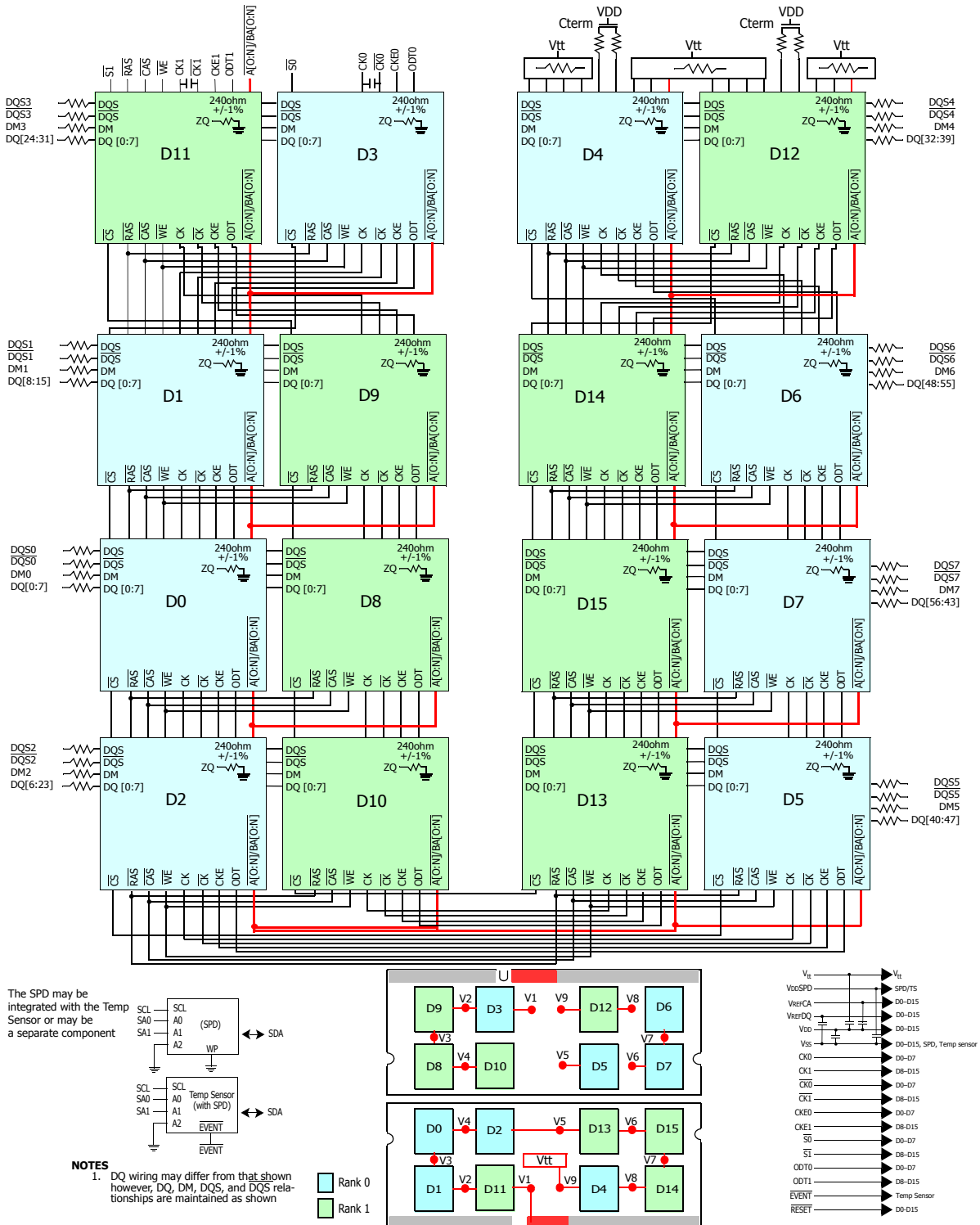
1. DQ wiring may differ from that shown however, DQ, DM, DQS, and DQS relationships are maintained as shown

■ Rank 0  
■ Rank 1

## 4GB, 512Mx64 Module(1Rank of x8)



### 8GB, 1Gx64 Module(2Rank of x8)



## Absolute Maximum Ratings

### Absolute Maximum DC Ratings

#### Absolute Maximum DC Ratings

| Symbol                             | Parameter                           | Rating          | Units | Notes |
|------------------------------------|-------------------------------------|-----------------|-------|-------|
| VDD                                | Voltage on VDD pin relative to Vss  | - 0.4 V ~ 1.8 V | V     | 1, 3  |
| VDDQ                               | Voltage on VDDQ pin relative to Vss | - 0.4 V ~ 1.8 V | V     | 1, 3  |
| V <sub>IN</sub> , V <sub>OUT</sub> | Voltage on any pin relative to Vss  | - 0.4 V ~ 1.8 V | V     | 1     |
| T <sub>STG</sub>                   | Storage Temperature                 | -55 to +100     | °C    | 1, 2  |

#### Notes:

1. Stresses greater than those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
2. Storage Temperature is the case surface temperature on the center/top side of the DRAM. For the measurement conditions, please refer to JEDEC standard.
3. VDD and VDDQ must be within 300mV of each other at all times; and VREF must not be greater than 0.6XVDDQ. When VDD and VDDQ are less than 500mV; VREF may be equal to or less than 300mV.

### DRAM Component Operating Temperature Range

#### Temperature Range

| Symbol            | Parameter                          | Rating   | Units | Notes |
|-------------------|------------------------------------|----------|-------|-------|
| T <sub>OPER</sub> | Normal Operating Temperature Range | 0 to 85  | °C    | 1,2   |
|                   | Extended Temperature Range         | 85 to 95 | °C    | 1,3   |

#### Notes:

1. Operating Temperature TOPER is the case surface temperature on the center / top side of the DRAM. For measurement conditions, please refer to the JEDEC document JEDEC51-2.
2. The Normal Temperature Range specifies the temperatures where all DRAM specifications will be supported. During operation, the DRAM case temperature must be maintained between 0 - 85°C under all operating conditions.
3. Some applications require operation of the DRAM in the Extended Temperature Range between 85°C and 95°C case temperature. Full specifications are guaranteed in this range, but the following additional conditions apply:
  - a. Refresh commands must be doubled in frequency, therefore reducing the Refresh interval tREFI to 3.9 μs. It is also possible to specify a component with 1X refresh (tREFI to 7.8μs) in the Extended Temperature Range. Please refer to the DIMM SPD for option availability
  - b. If Self-Refresh operation is required in the Extended Temperature Range, then it is mandatory to use the Manual Self-Refresh mode with Extended Temperature Range capability (MR2 A6 = 0b and MR2 A7 = 1b). DDR3 SDRAMs support Extended Temperature Range and please refer to component datasheet and/or the DIMM SPD for tREFI requirements in the Extended Temperature Range.

## AC & DC Operating Conditions

### Recommended DC Operating Conditions

#### Recommended DC Operating Conditions - DDR3L (1.35V) operation

| Symbol | Parameter                 | Rating |      |      | Units | Notes   |
|--------|---------------------------|--------|------|------|-------|---------|
|        |                           | Min.   | Typ. | Max. |       |         |
| VDD    | Supply Voltage            | 1.283  | 1.35 | 1.45 | V     | 1,2,3,4 |
| VDDQ   | Supply Voltage for Output | 1.283  | 1.35 | 1.45 | V     | 1,2,3,4 |

#### Notes:

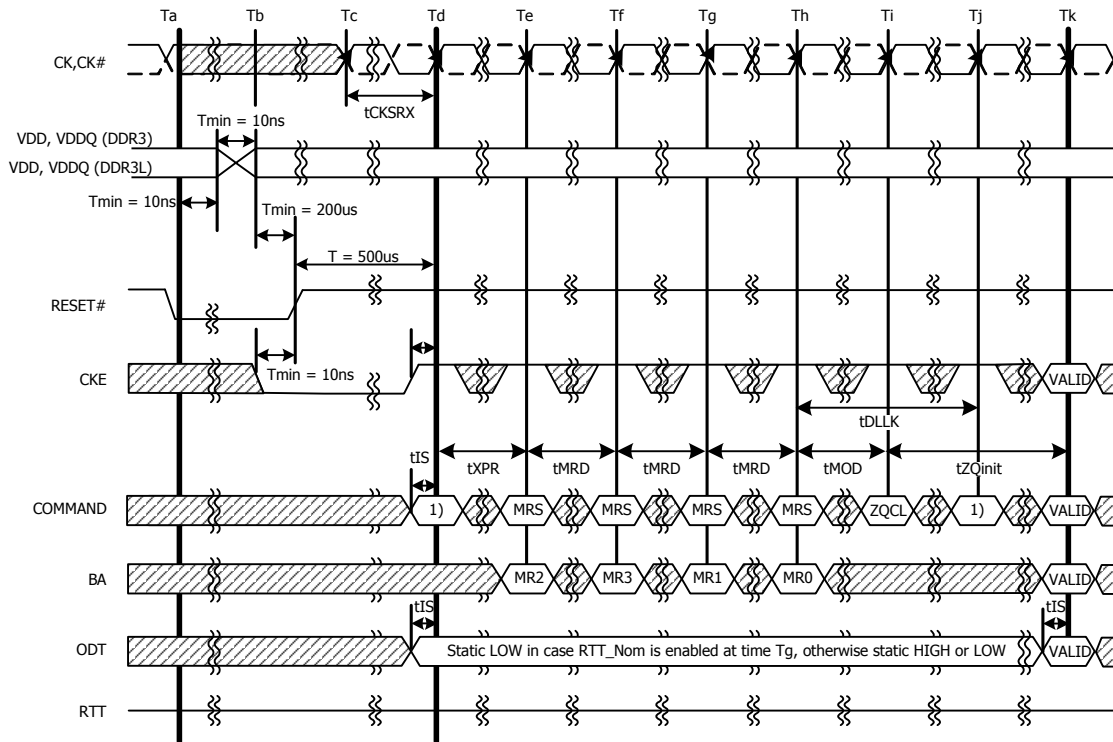
1. Maximum DC value may not be greater than 1.425V. The DC value is the linear average of VDD/VDDQ (t) over a very long period of time (e.g., 1 sec).
2. If maximum limit is exceeded, input levels shall be governed by DDR3 specifications.
3. Under these supply voltages, the device operates to this DDR3L specification.
4. Once initialized for DDR3L operation, DDR3 operation may only be used if the device is in reset while VDD and VDDQ are changed for DDR3 operation (see Figure 0).

#### Recommended DC Operating Conditions - - DDR3 (1.5V) operation

|      | Parameter                 | Rating |      |       | Units | Notes |
|------|---------------------------|--------|------|-------|-------|-------|
|      |                           | Min.   | Typ. | Max.  |       |       |
| VDD  | Supply Voltage            | 1.425  | 1.5  | 1.575 | V     | 1,2,3 |
| VDDQ | Supply Voltage for Output | 1.425  | 1.5  | 1.575 | V     | 1,2,3 |

#### Notes:

1. If minimum limit is exceeded, input levels shall be governed by DDR3L specifications.
2. Under 1.5V operation, this DDR3L device operates to the DDR3 specifications under the same speed timings as defined for this device.
3. Once initialized for DDR3 operation, DDR3L operation may only be used if the device is in reset while VDD and VDDQ are changed for DDR3L operation (see Figure 0).



NOTE 1: From time point "Td" until "Tk" NOP or DES commands must be applied between MRS and ZQCL commands.

TIME BREAK DON'T CARE

Figure 0 - VDD/VDDQ Voltage Switch Between DDR3L and DDR3

## AC & DC Input Measurement Levels

### AC and DC Logic Input Levels for Single-Ended Signals

### AC and DC Input Levels for Single-Ended Command and Address Signals

#### Single Ended AC and DC Input Levels for Command and Address

| Symbol                 | Parameter                             | DDR3L-800/1066 |              | DDR3L-1333/1600 |              | DDR3L-1866   |              | Unit | Notes |
|------------------------|---------------------------------------|----------------|--------------|-----------------|--------------|--------------|--------------|------|-------|
|                        |                                       | Min            | Max          | Min             | Max          | Min          | Max          |      |       |
| VIH.CA(DC90)           | DC input logic high                   | Vref + 0.09    | VDD          | Vref + 0.09     | VDD          | Vref + 0.09  | VDD          | V    | 1     |
| VIL.CA(DC90)           | DC input logic low                    | VSS            | Vref - 0.09  | VSS             | Vref - 0.09  | VSS          | Vref - 0.09  | V    | 1     |
| VIH.CA(AC160)          | AC input logic high                   | Vref + 0.160   | Note2        | Vref + 0.160    | Note2        | -            | -            | V    | 1,2,5 |
| VIL.CA(AC160)          | AC input logic low                    | Note2          | Vref - 0.160 | Note2           | Vref - 0.160 | -            | -            | V    | 1,2,5 |
| VIH.CA(AC135)          | AC Input logic high                   | Vref + 0.135   | Note2        | Vref + 0.135    | Note2        | Vref + 0.135 | Note2        | V    | 1,2,5 |
| VIL.CA(AC135)          | AC input logic low                    | Note2          | Vref - 0.135 | Note2           | Vref - 0.135 | Note2        | Vref - 0.135 | V    | 1,2,5 |
| VIH.CA(AC125)          | AC Input logic high                   | -              | -            | -               | -            | Vref + 0.125 | Note2        | V    | 1,2,5 |
| VIL.CA(AC125)          | AC input logic low                    | -              | -            | -               | -            | Note2        | Vref - 0.125 | V    | 1,2,5 |
| V <sub>RefCA(DC)</sub> | Reference Voltage for ADD, CMD inputs | 0.49 * VDD     | 0.51 * VDD   | 0.49 * VDD      | 0.51 * VDD   | 0.49 * VDD   | 0.51 * VDD   | V    | 3,4   |

#### Notes:

1. For input only pins except  $\overline{\text{RESET}}$ , Vref = VrefCA (DC).
2. Refer to "Overshoot and Undershoot Specifications" on page 29.
3. The ac peak noise on V<sub>Ref</sub> may not allow V<sub>Ref</sub> to deviate from V<sub>RefCA(DC)</sub> by more than +/-1% VDD (for reference: approx. +/- 13.5 mV).
4. For reference: approx. VDD/2 +/- 13.5 mV
5. These levels apply for 1.35 volt (see table above) operation only. If the device is operated at 1.5V (table "Single Ended AC and DC Input Levels for DQ and DM" on page 17), the respective levels in JESD79-3 (VIH/L.CA(DC100), VIH/L.CA(AC175), VIH/L.CA(AC150), VIH/L.CA(AC135), VIH/L.CA(AC125) etc.) apply. The 1.5V levels (VIH/L.CA(DC100), VIH/L.CA(AC175), VIH/L.CA(AC150), VIH/L.CA(AC135), VIH/L.CA(AC125) etc.) do not apply when the device is operated in the 1.35 voltage range.

## AC and DC Input Levels for Single-Ended Signals

DDR3 SDRAM will support two Vih/Vil AC levels for DDR3-800 and DDR3-1066s specified in table below. DDR3 SDRAM will also support corresponding tDS values (Table 43 and Table 50 in "DDR3L Device Operation") as well as derating tables Table 46 in "DDR3L Device Operation" depending on Vih/Vil AC levels.

### Single Ended AC and DC Input Levels for DQ and DM

| Symbol                 | Parameter                           | DDR3L-800/1066 |              | DDR3L-1333/1600 |              | DDR3L-1866   |              | Unit | Notes   |
|------------------------|-------------------------------------|----------------|--------------|-----------------|--------------|--------------|--------------|------|---------|
|                        |                                     | Min            | Max          | Min             | Max          | Min          | Max          |      |         |
| VIH.DQ(DC90)           | DC input logic high                 | Vref + 0.09    | VDD          | Vref + 0.09     | VDD          | Vref + 0.09  | VDD          | V    | 1       |
| VIL.DQ(DC90)           | DC input logic low                  | VSS            | Vref - 0.09  | VSS             | Vref - 0.09  | VSS          | Vref - 0.09  | V    | 1       |
| VIH.DQ(AC160)          | AC input logic high                 | Vref + 0.160   | Note2        | -               | -            | -            | -            | V    | 1, 2, 5 |
| VIL.DQ(AC160)          | AC input logic low                  | Note2          | Vref - 0.160 | -               | -            | -            | -            | V    | 1, 2, 5 |
| VIH.DQ(AC135)          | AC Input logic high                 | Vref + 0.135   | Note2        | Vref + 0.135    | Note2        | -            | -            | V    | 1, 2, 5 |
| VIL.DQ(AC135)          | AC input logic low                  | Note2          | Vref - 0.135 | Note2           | Vref - 0.135 | -            | -            | V    | 1, 2, 5 |
| VIH.DQ(AC130)          | AC Input logic high                 | -              | -            | -               | -            | Vref + 0.130 | Note2        | V    | 1, 2, 5 |
| VIL.DQ(AC130)          | AC input logic low                  | -              | -            | -               | -            | Note2        | Vref - 0.130 | V    | 1, 2, 5 |
| V <sub>RefDQ(DC)</sub> | Reference Voltage for DQ, DM inputs | 0.49 * VDD     | 0.51 * VDD   | 0.49 * VDD      | 0.51 * VDD   | 0.49 * VDD   | 0.51 * VDD   | V    | 3, 4    |

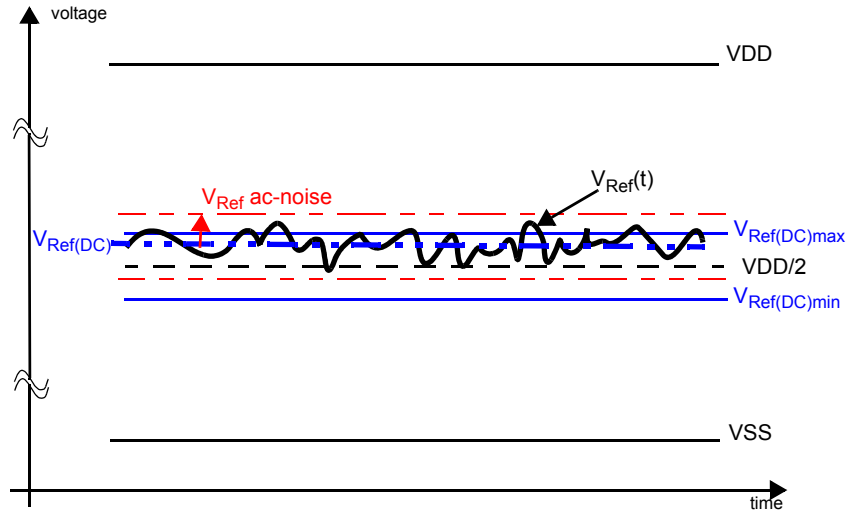
#### Notes:

1. Vref = VrefDQ (DC).
2. Refer to "Overshoot and Undershoot Specifications" on page 29.
3. The ac peak noise on V<sub>Ref</sub> may not allow V<sub>Ref</sub> to deviate from V<sub>RefDQ(DC)</sub> by more than +/-1% VDD (for reference: approx. +/- 13.5 mV).
4. For reference: approx. VDD/2 +/- 13.5 mV
5. These levels apply for 1.35 volt (table "Single Ended AC and DC Input Levels for Command and Address" on page 16) operation only. If the device is operated at 1.5V (table above), the respective levels in JESD79-3 (VIH/L.DQ(DC100), VIH/L.DQ(AC175), VIH/L.DQ(AC150), VIH/L.DQ(AC135) etc.) apply. The 1.5V levels (VIH/L.DQ(DC100), VIH/L.DQ(AC175), VIH/L.DQ(AC150), VIH/L.DQ(AC135) etc.) do not apply when the device is operated in the 1.35 voltage range.

## Vref Tolerances

The dc-tolerance limits and ac-noise limits for the reference voltages  $V_{\text{RefCA}}$  and  $V_{\text{RefDQ}}$  are illustrated in figure below. It shows a valid reference voltage  $V_{\text{Ref}}(t)$  as a function of time. ( $V_{\text{Ref}}$  stands for  $V_{\text{RefCA}}$  and  $V_{\text{RefDQ}}$  likewise).

$V_{\text{Ref}}(\text{DC})$  is the linear average of  $V_{\text{Ref}}(t)$  over a very long period of time (e.g. 1 sec). This average has to meet the min/max requirements in the table "Differential Input Slew Rate Definition" on page 24. Furthermore  $V_{\text{Ref}}(t)$  may temporarily deviate from  $V_{\text{Ref}}(\text{DC})$  by no more than  $\pm 1\% \text{ VDD}$ .



**Illustration of  $V_{\text{Ref}}(\text{DC})$  tolerance and  $V_{\text{Ref}}$  ac-noise limits**

The voltage levels for setup and hold time measurements  $V_{\text{IH}}(\text{AC})$ ,  $V_{\text{IH}}(\text{DC})$ ,  $V_{\text{IL}}(\text{AC})$ , and  $V_{\text{IL}}(\text{DC})$  are dependent on  $V_{\text{Ref}}$ .

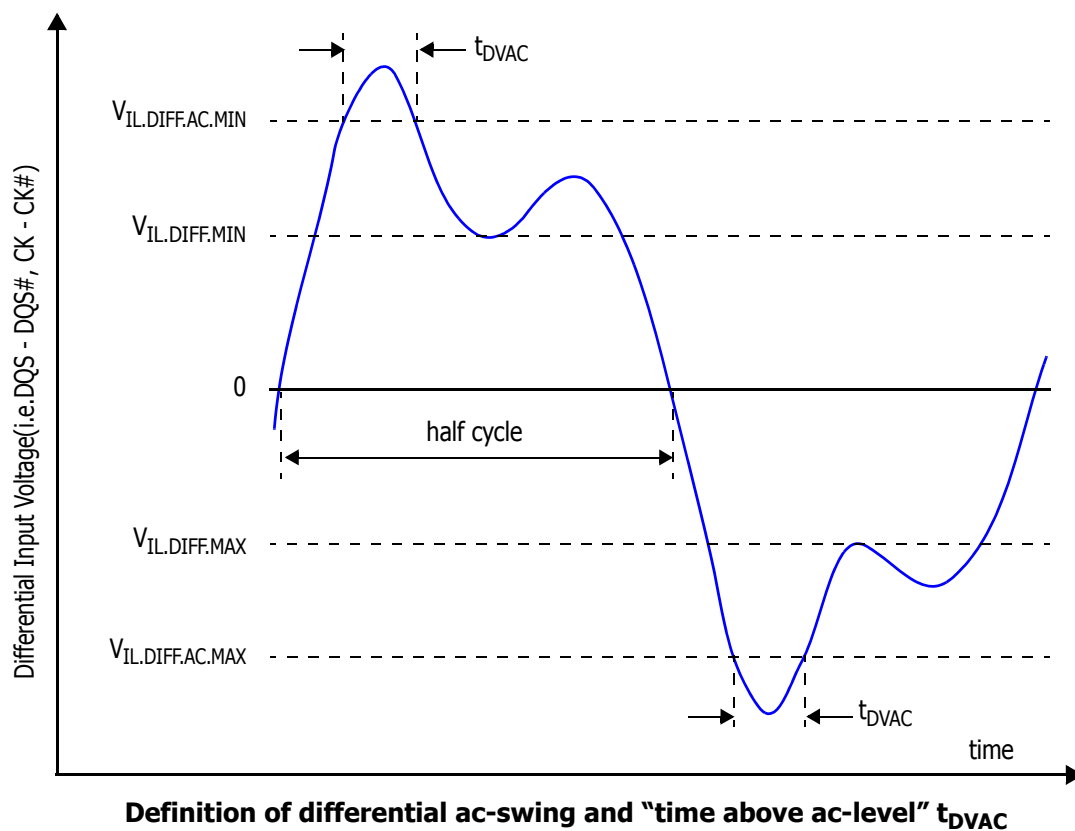
" $V_{\text{Ref}}$ " shall be understood as  $V_{\text{Ref}}(\text{DC})$ , as defined in figure above.

This clarifies that dc-variations of  $V_{\text{Ref}}$  affect the absolute voltage a signal has to reach to achieve a valid high or low level and therefore the time to which setup and hold is measured. System timing and voltage budgets need to account for  $V_{\text{Ref}}(\text{DC})$  deviations from the optimum position within the data-eye of the input signals.

This also clarifies that the DRAM setup/hold specification and derating values need to include time and voltage associated with  $V_{\text{Ref}}\text{ac-noise}$ . Timing and voltage effects due to ac-noise on  $V_{\text{Ref}}$  up to the specified limit ( $\pm 1\%$  of VDD) are included in DRAM timings and their associated deratings.

## AC and DC Logic Input Levels for Differential Signals

### Differential signal definition



## Differential swing requirements for clock (CK - $\overline{\text{CK}}$ ) and strobe (DQS - $\overline{\text{DQS}}$ )

### Differential AC and DC Input Levels

| Symbol            | Parameter                    | DDR3L-800, 1066, 1333, 1600, 1866 |                                   | Unit | Notes |
|-------------------|------------------------------|-----------------------------------|-----------------------------------|------|-------|
|                   |                              | Min                               | Max                               |      |       |
| $V_{IHdiff}$      | Differential input high      | + 0.180                           | Note 3                            | V    | 1     |
| $V_{ILdiff}$      | Differential input logic low | Note 3                            | - 0.180                           | V    | 1     |
| $V_{IHdiff} (ac)$ | Differential input high ac   | 2 x ( $V_{IH} (ac)$ - $V_{ref}$ ) | Note 3                            | V    | 2     |
| $V_{ILdiff} (ac)$ | Differential input low ac    | Note 3                            | 2 x ( $V_{IL} (ac)$ - $V_{ref}$ ) | V    | 2     |

#### Notes:

- Used to define a differential signal slew-rate.
- For CK -  $\overline{\text{CK}}$  use  $V_{IH}/V_{IL} (ac)$  of AADD/CMD and  $V_{REFCA}$ ; for DQS -  $\overline{\text{DQS}}$ ,  $\text{DQSL}$ ,  $\overline{\text{DQSL}}$ ,  $\text{DQSU}$ ,  $\overline{\text{DQSU}}$  use  $V_{IH}/V_{IL} (ac)$  of DQs and  $V_{REFDQ}$ ; if a reduced ac-high or ac-low levels is used for a signal group, then the reduced level applies also here.
- These values are not defined; however, the single-ended signals  $\text{Ck}$ ,  $\overline{\text{CK}}$ ,  $\text{DQS}$ ,  $\overline{\text{DQS}}$ ,  $\text{DQSL}$ ,  $\overline{\text{DQSL}}$ ,  $\text{DQSU}$ ,  $\overline{\text{DQSU}}$  need to be within the respective limits ( $V_{IH} (dc)$  max,  $V_{IL} (dc)$  min) for single-ended signals as well as the limitations for overshoot and undershoot. Refer to "Overshoot and Undershoot Specifications" on page 29.

### Allowed time before ringback ( $t_{DVAC}$ ) for CK - $\overline{\text{CK}}$ and DQS - $\overline{\text{DQS}}$

| Slew Rate<br>[V/ns] | DDR3L-800/1066/1333/1600                              |     |                                                       |     | DDR3L-1866                                            |     |                                                       |     |                                                       |     |
|---------------------|-------------------------------------------------------|-----|-------------------------------------------------------|-----|-------------------------------------------------------|-----|-------------------------------------------------------|-----|-------------------------------------------------------|-----|
|                     | $t_{DVAC} [ps]$<br>@ $ V_{IH}/L_{diff} (ac)  = 320mV$ |     | $t_{DVAC} [ps]$<br>@ $ V_{IH}/L_{diff} (ac)  = 270mV$ |     | $t_{DVAC} [ps]$<br>@ $ V_{IH}/L_{diff} (ac)  = 270mV$ |     | $t_{DVAC} [ps]$<br>@ $ V_{IH}/L_{diff} (ac)  = 250mV$ |     | $t_{DVAC} [ps]$<br>@ $ V_{IH}/L_{diff} (ac)  = 260mV$ |     |
|                     | min                                                   | max | min                                                   | max | min                                                   | max | min                                                   | max | min                                                   | max |
| > 4.0               | 189                                                   | -   | 201                                                   | -   | 163                                                   | -   | 168                                                   | -   | 176                                                   | -   |
| 4.0                 | 189                                                   | -   | 201                                                   | -   | 163                                                   | -   | 168                                                   | -   | 176                                                   | -   |
| 3.0                 | 162                                                   | -   | 179                                                   | -   | 140                                                   | -   | 147                                                   | -   | 154                                                   | -   |
| 2.0                 | 109                                                   | -   | 134                                                   | -   | 95                                                    | -   | 105                                                   | -   | 111                                                   | -   |
| 1.8                 | 91                                                    | -   | 119                                                   | -   | 80                                                    | -   | 91                                                    | -   | 97                                                    | -   |
| 1.6                 | 69                                                    | -   | 100                                                   | -   | 62                                                    | -   | 74                                                    | -   | 78                                                    | -   |
| 1.4                 | 40                                                    | -   | 76                                                    | -   | 37                                                    | -   | 52                                                    | -   | 56                                                    | -   |
| 1.2                 | note                                                  | -   | 44                                                    | -   | 5                                                     | -   | 22                                                    | -   | 24                                                    | -   |
| 1.0                 | note                                                  | -   | note                                                  | -   | note                                                  | -   | note                                                  | -   | note                                                  | -   |
| < 1.0               | note                                                  | -   | note                                                  | -   | note                                                  | -   | note                                                  | -   | note                                                  | -   |

note : Rising input signal shall become equal to or greater than  $V_{IH}(ac)$  level and Falling input signal shall become equal to or less than  $V_{IL}(ac)$  level.

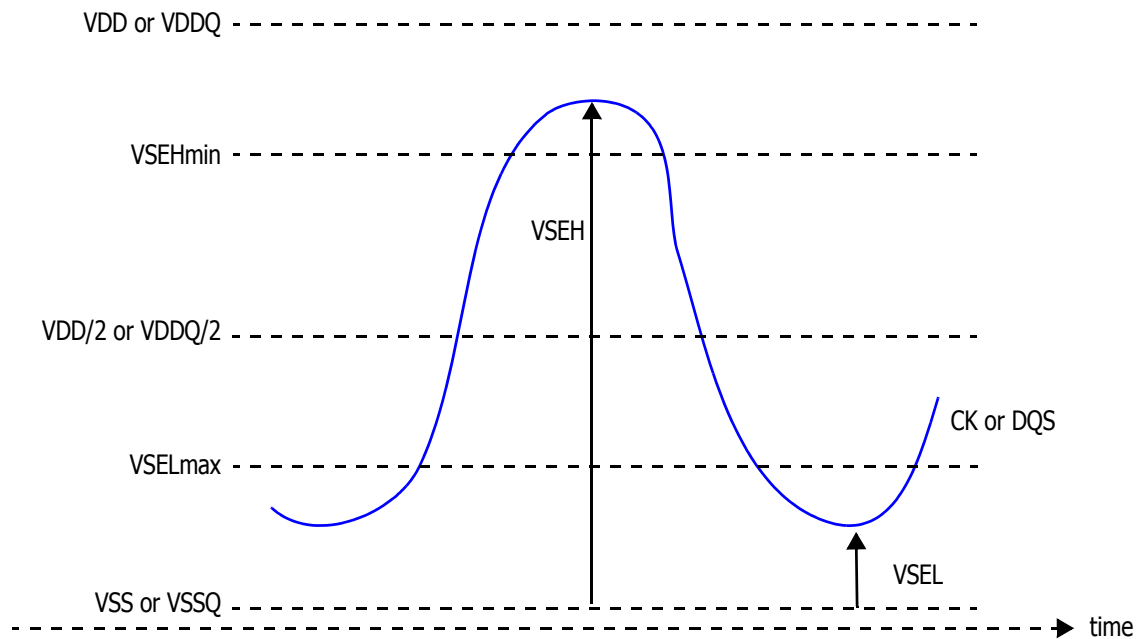
## Single-ended requirements for differential signals

Each individual component of a differential signal (CK, DQS, DQSL, DQSU,  $\overline{\text{CK}}$ ,  $\overline{\text{DQS}}$ ,  $\overline{\text{DQSL}}$ , or  $\overline{\text{DQSU}}$ ) also has to comply with certain requirements for single-ended signals.

CK and  $\overline{\text{CK}}$  have to approximately reach VSEHmin / VSELmax (approximately equal to the ac-levels (VIH (ac) / VIL (ac)) for ADD/CMD signals) in every half-cycle.

DQS, DQSL, DQSU,  $\overline{\text{DQS}}$ ,  $\overline{\text{DQSL}}$  have to reach VSEHmin / VSELmax (approximately the ac-levels (VIH (ac) / VIL (ac)) for DQ signals) in every half-cycle preceding and following a valid transition.

Note that the applicable ac-levels for ADD/CMD and DQ's might be different per speed-bin etc. E.g., if VIH.CA(AC150)/VIL.CA(AC150) is used for ADD/CMD signals, then these ac-levels apply also for the single-ended signals CK and  $\overline{\text{CK}}$ .



### Single-ended requirements for differential signals.

Note that, while ADD/CMD and DQ signal requirements are with respect to Vref, the single-ended components of differential signals have a requirement with respect to VDD / 2; this is nominally the same. The transition of single-ended signals through the ac-levels is used to measure setup time. For single-ended components of differential signals the requirement to reach VSELmax, VSEHmin has no bearing on timing, but adds a restriction on the common mode characteristics of these signals.

### Single-ended levels for CK, DQS, DQSL, DQSU, $\overline{\text{CK}}$ , $\overline{\text{DQS}}$ , $\overline{\text{DQSL}}$ or $\overline{\text{DQSU}}$

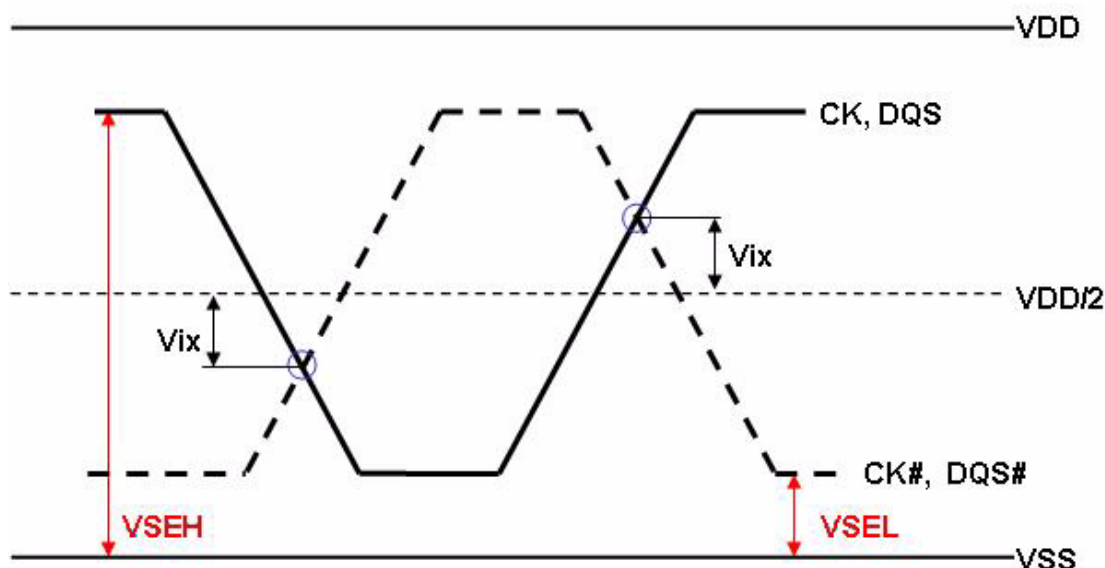
|      | Parameter                                              | DDR3L-800, 1066, 1333, 1600, 1866 |                            | Unit | Notes |
|------|--------------------------------------------------------|-----------------------------------|----------------------------|------|-------|
|      |                                                        | Min                               | Max                        |      |       |
| VSEH | Single-ended high level for strobes                    | $(\text{VDD} / 2) + 0.175$        | Note 3                     | V    | 1,2   |
|      | Single-ended high level for Ck, $\overline{\text{CK}}$ | $(\text{VDD} / 2) + 0.175$        | Note 3                     | V    | 1,2   |
| VSEL | Single-ended low level for strobes                     | Note 3                            | $(\text{VDD} / 2) - 0.175$ | V    | 1,2   |
|      | Single-ended low level for CK, $\overline{\text{CK}}$  | Note 3                            | $(\text{VDD} / 2) - 0.175$ | V    | 1,2   |

#### Notes:

1. For CK,  $\overline{\text{CK}}$  use VIH/VIL (ac) of ADD/CMD; for strobes (DQS,  $\overline{\text{DQS}}$ , DQSL,  $\overline{\text{DQSL}}$ , DQSU,  $\overline{\text{DQSU}}$ ) use VIH/VIL (ac) of DQs.
2. VIH (ac)/VIL (ac) for DQs is based on VREFDQ; VIH (ac)/VIL (ac) for ADD/CMD is based on VREFCA; if a reduced ac-high or ac-low level is used for a signal group, then the reduced level applies also here.
3. These values are not defined; however, the single-ended signals Ck,  $\overline{\text{CK}}$ , DQS,  $\overline{\text{DQS}}$ , DQSL,  $\overline{\text{DQSL}}$ , DQSU,  $\overline{\text{DQSU}}$  need to be within the respective limits (VIH (dc) max, VIL (dc) min) for single-ended signals as well as the limitations for overshoot and undershoot. Refer to "Overshoot and Undershoot Specifications" on page 29.

## Differential Input Cross Point Voltage

To guarantee tight setup and hold times as well as output skew parameters with respect to clock and strobe, each cross point voltage of differential input signals (CK,  $\overline{\text{CK}}$  and DQS,  $\overline{\text{DQS}}$ ) must meet the requirements in the table below. The differential input cross point voltage  $V_{IX}$  is measured from the actual cross point of true and complement signals to the midlevel between of VDD and VSS



**Vix Definition**  
**Vix Definition**

### Cross point voltage for differential input signals (CK, DQS)

|                      | Parameter                                                                                 | DDR3L-800, 1066, 1333, 1600, 1866 |     | Unit | Notes |
|----------------------|-------------------------------------------------------------------------------------------|-----------------------------------|-----|------|-------|
|                      |                                                                                           | Min                               | Max |      |       |
| $V_{IX}(\text{CK})$  | Differential Input Cross Point Voltage relative to VDD/2 for CK, $\overline{\text{CK}}$   | -150                              | 150 | mV   | 2     |
|                      |                                                                                           | -175                              | 175 | mV   | 1     |
| $V_{IX}(\text{DQS})$ | Differential Input Cross Point Voltage relative to VDD/2 for DQS, $\overline{\text{DQS}}$ | -150                              | 150 | mV   | 2     |

#### Notes:

- Extended range for  $V_{IX}$  is only allowed for clock and if single-ended clock input signals CK and  $\overline{\text{CK}}$  are monotonic with a single-ended swing VSEL / VSEH of at least VDD/2 +/-250 mV, and when the differential slew rate of CK -  $\overline{\text{CK}}$  is larger than 3 V/ns.
- The relation between Vix Min/Max and VSEL/VSEH should satisfy following.  
 $(\text{VDD}/2) + V_{ix}(\text{Min}) - \text{VSEL} \geq 25\text{mV}$   
 $\text{VSEH} - ((\text{VDD}/2) + V_{ix}(\text{Max})) \geq 25\text{mV}$

## Slew Rate Definitions for Single-Ended Input Signals

See 7.5 "Address / Command Setup, Hold and Derating" in "DDR3L Device Operation" for single-ended slew rate definitions for address and command signals.

See 7.6 "Data Setup, Hold and Slew Rate Derating" in "DDR3L Device Operation" for single-ended slew rate definition for data signals.

## Slew Rate Definitions for Differential Input Signals

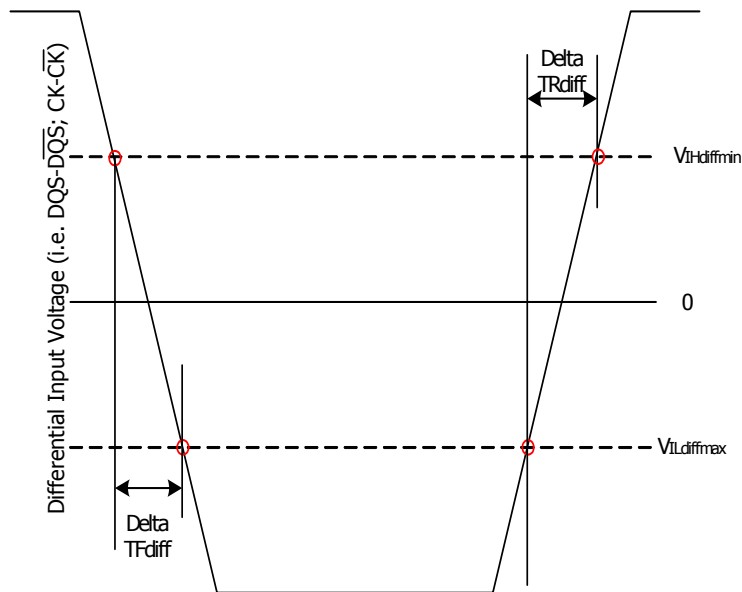
Input slew rate for differential signals (CK,  $\overline{\text{CK}}$  and DQS,  $\overline{\text{DQS}}$ ) are defined and measured as shown in table and figure below.

### Differential Input Slew Rate Definition

| Description                                                                                                  | Measured               |                        | Defined by                                                            |
|--------------------------------------------------------------------------------------------------------------|------------------------|------------------------|-----------------------------------------------------------------------|
|                                                                                                              | Min                    | Max                    |                                                                       |
| Differential input slew rate for rising edge (CK- $\overline{\text{CK}}$ and DQS- $\overline{\text{DQS}}$ )  | $V_{\text{ILdiffmax}}$ | $V_{\text{IHdiffmin}}$ | $[V_{\text{IHdiffmin}} - V_{\text{ILdiffmax}}] / \Delta\text{TRdiff}$ |
| Differential input slew rate for falling edge (CK- $\overline{\text{CK}}$ and DQS- $\overline{\text{DQS}}$ ) | $V_{\text{IHdiffmin}}$ | $V_{\text{ILdiffmax}}$ | $[V_{\text{IHdiffmin}} - V_{\text{ILdiffmax}}] / \Delta\text{TFdiff}$ |

#### Notes:

The differential signal (i.e. CK- $\overline{\text{CK}}$  and DQS- $\overline{\text{DQS}}$ ) must be linear between these thresholds.



### Differential Input Slew Rate Definition for DQS, $\overline{\text{DQS}}$ and CK, $\overline{\text{CK}}$

## AC & DC Output Measurement Levels

### Single Ended AC and DC Output Levels

Table below shows the output levels used for measurements of single ended signals.

#### Single-ended AC and DC Output Levels

| Symbol       | Parameter                                                 | DDR3L-800, 1066,<br>1333, 1600, 1866 | Unit | Notes |
|--------------|-----------------------------------------------------------|--------------------------------------|------|-------|
| $V_{OH(DC)}$ | DC output high measurement level (for IV curve linearity) | $0.8 \times V_{DDQ}$                 | V    |       |
| $V_{OM(DC)}$ | DC output mid measurement level (for IV curve linearity)  | $0.5 \times V_{DDQ}$                 | V    |       |
| $V_{OL(DC)}$ | DC output low measurement level (for IV curve linearity)  | $0.2 \times V_{DDQ}$                 | V    |       |
| $V_{OH(AC)}$ | AC output high measurement level (for output SR)          | $V_{TT} + 0.1 \times V_{DDQ}$        | V    | 1     |
| $V_{OL(AC)}$ | AC output low measurement level (for output SR)           | $V_{TT} - 0.1 \times V_{DDQ}$        | V    | 1     |

#### Notes:

1. The swing of  $\pm 0.1 \times V_{DDQ}$  is based on approximately 50% of the static single ended output high or low swing with a driver impedance of  $40\Omega$  and an effective test load of  $25\Omega$  to  $V_{TT} = V_{DDQ} / 2$ .

### Differential AC and DC Output Levels

Table below shows the output levels used for measurements of single ended signals.

#### Differential AC and DC Output Levels

| Symbol           | Parameter                                                     | DDR3L-800, 1066,<br>1333, 1600, 1866 | Unit | Notes |
|------------------|---------------------------------------------------------------|--------------------------------------|------|-------|
| $V_{OHdiff(AC)}$ | AC differential output high measurement level (for output SR) | $+ 0.2 \times V_{DDQ}$               | V    | 1     |
| $V_{OLdiff(AC)}$ | AC differential output low measurement level (for output SR)  | $- 0.2 \times V_{DDQ}$               | V    | 1     |

#### Notes:

1. The swing of  $\pm 0.2 \times V_{DDQ}$  is based on approximately 50% of the static differential output high or low swing with a driver impedance of  $40\Omega$  and an effective test load of  $25\Omega$  to  $V_{TT} = V_{DDQ}/2$  at each of the differential outputs.

## Single Ended Output Slew Rate

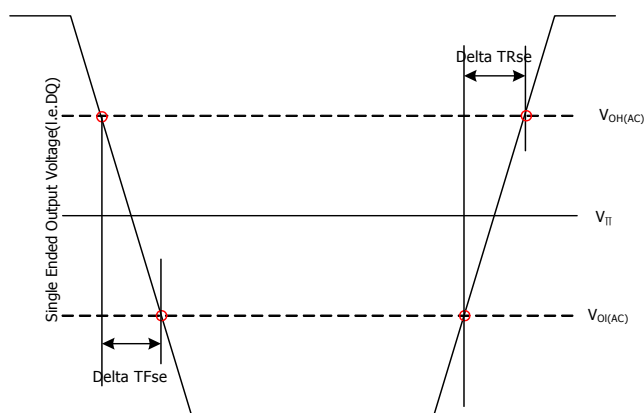
When the Reference load for timing measurements, output slew rate for falling and rising edges is defined and measured between  $V_{OL(AC)}$  and  $V_{OH(AC)}$  for single ended signals are shown in table and Figure below.

### Single-ended Output slew Rate Definition

| Description                                    | Measured     |              | Defined by                                   |
|------------------------------------------------|--------------|--------------|----------------------------------------------|
|                                                | From         | To           |                                              |
| Single-ended output slew rate for rising edge  | $V_{OL(AC)}$ | $V_{OH(AC)}$ | $[V_{OH(AC)} - V_{OL(AC)}] / \Delta TR_{se}$ |
| Single-ended output slew rate for falling edge | $V_{OH(AC)}$ | $V_{OL(AC)}$ | $[V_{OH(AC)} - V_{OL(AC)}] / \Delta TF_{se}$ |

#### Notes:

- Output slew rate is verified by design and characterisation, and may not be subject to production test.



### Single Ended Output slew Rate Definition

### Output Slew Rate (single-ended)

|                               |        | DDR3L-800 |                 | DDR3L-1066 |                 | DDR3L-1333 |                 | DDR3L-1600 |                 | DDR3L-1866 |                 | Units |
|-------------------------------|--------|-----------|-----------------|------------|-----------------|------------|-----------------|------------|-----------------|------------|-----------------|-------|
| Parameter                     | Symbol | Min       | Max             | Min        | Max             | Min        | Max             | Min        | Max             | Min        | Max             |       |
| Single-ended Output Slew Rate | SRQse  | 1.75      | 5 <sup>1)</sup> | 1.75       | 5 <sup>1)</sup> | 1.75       | 5 <sup>1)</sup> | 1.75       | 5 <sup>1)</sup> | 1.75       | 5 <sup>1)</sup> | V/ns  |

Description: SR; Slew Rate

Q: Query Output (like in DQ, which stands for Data-in, Query-Output)

se: Single-ended Signals

For Ron = RZQ/7 setting

Note 1): In two cases, a maximum slew rate of 6V/ns applies for a single DQ signal within a byte lane.

Case 1 is a defined for a single DQ signal within a byte lane which is switching into a certain direction (either from high to low or low to high) while all remaining DQ signals in the same byte lane are static (i.e. they stay at either high or low).

Case 2 is a defined for a single DQ signal within a byte lane which is switching into a certain direction (either from high to low or low to high) while all remaining DQ signals in the same byte lane switching into the opposite direction (i.e. from low to high or high to low respectively). For the remaining DQ signal switching in to the opposite direction, the regular maximum limite of 5 V/ns applies.

## Differential Output Slew Rate

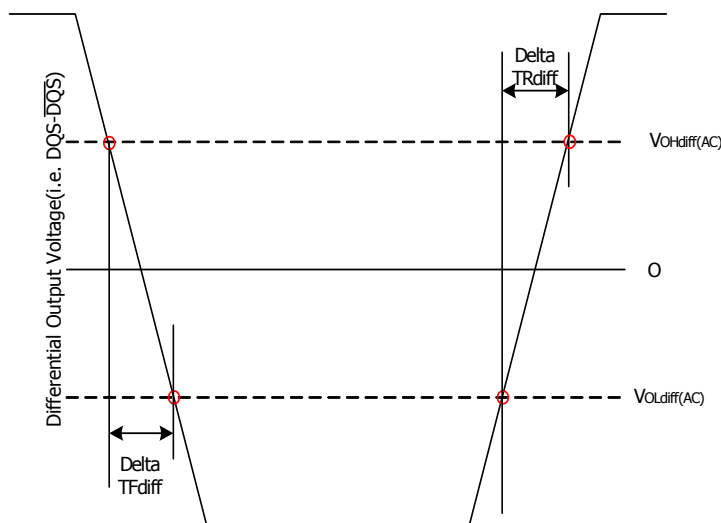
With the reference load for timing measurements, output slew rate for falling and rising edges is defined and measured between VOLdiff (AC) and VOHdiff (AC) for differential signals as shown in table and figure below.

### Differential Output Slew Rate Definition

| Description                                    | Measured                 |                          | Defined by                                               |
|------------------------------------------------|--------------------------|--------------------------|----------------------------------------------------------|
|                                                | From                     | To                       |                                                          |
| Differential output slew rate for rising edge  | V <sub>OLdiff</sub> (AC) | V <sub>OHdiff</sub> (AC) | $[V_{OHdiff} (AC) - V_{OLdiff} (AC)] / \Delta TR_{diff}$ |
| Differential output slew rate for falling edge | V <sub>OHdiff</sub> (AC) | V <sub>OLdiff</sub> (AC) | $[V_{OHdiff} (AC) - V_{OLdiff} (AC)] / \Delta TF_{diff}$ |

#### Notes:

- Output slew rate is verified by design and characterization, and may not be subject to production test.



### Differential Output slew Rate Definition

### Differential Output Slew Rate

|                               |         | DDR3L-800 |     | DDR3L-1066 |     | DDR3L-1333 |     | DDR3L-1600 |     | DDR3L-1866 |     | Units |
|-------------------------------|---------|-----------|-----|------------|-----|------------|-----|------------|-----|------------|-----|-------|
| Parameter                     | Symbol  | Min       | Max | Min        | Max | Min        | Max | Min        | Max | Min        | Max |       |
| Differential Output Slew Rate | SRQdiff | 3.5       | 12  | 3.5        | 12  | 3.5        | 12  | 3.5        | 12  | 3.5        | 12  | V/ns  |

Description: SR; Slew Rate

Q: Query Output (like in DQ, which stands for Data-in, Query-Output)

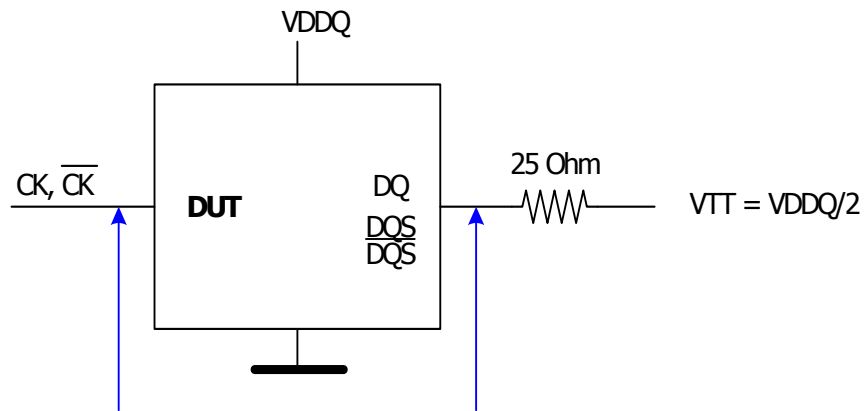
se: Single-ended Signals

For Ron = RZQ/7 setting

## Reference Load for AC Timing and Output Slew Rate

Figure below represents the effective reference load of 25 ohms used in defining the relevant AC timing parameters of the device as well as output slew rate measurements.

It is not intended as a precise representation of any particular system environment or a depiction of the actual load presented by a production tester. System designers should use IBIS or other simulation tools to correlate the timing reference load to a system environment. Manufacturers correlate to their production test conditions, generally one or more coaxial transmission lines terminated at the tester electronics.



**Reference Load for AC Timing and Output Slew Rate**

## Overshoot and Undershoot Specifications

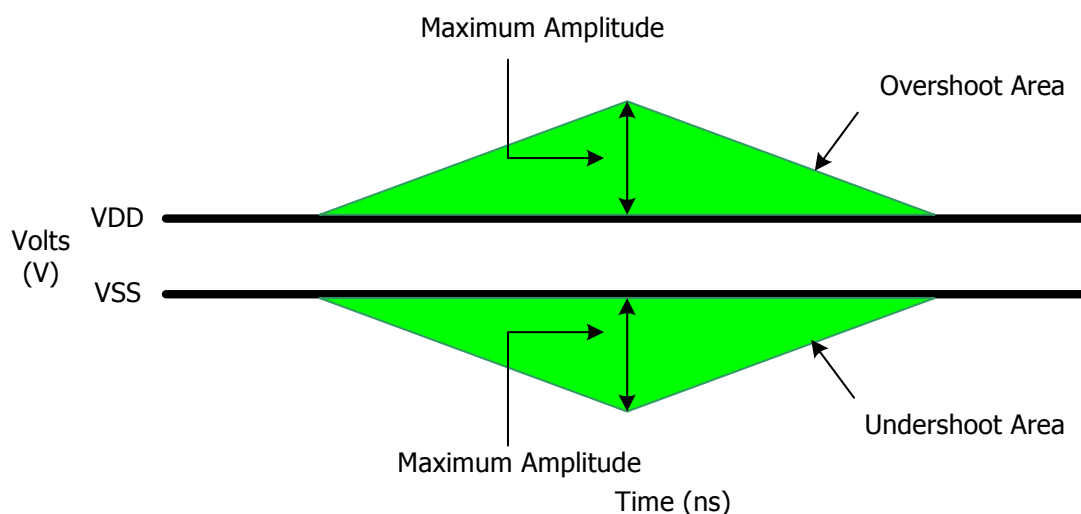
### Address and Control Overshoot and Undershoot Specifications

#### AC Overshoot/Undershoot Specification for Address and Control Pins

| Parameter                                                              | DDR3<br>L-800 | DDR3<br>L-1066 | DDR3<br>L-1333 | DDR3<br>L-1600 | DDR3<br>L-1866 | Units |
|------------------------------------------------------------------------|---------------|----------------|----------------|----------------|----------------|-------|
|                                                                        |               |                |                |                |                |       |
| Maximum peak amplitude allowed for overshoot area. (See Figure below)  | 0.4           | 0.4            | 0.4            | 0.4            | 0.4            | V     |
| Maximum peak amplitude allowed for undershoot area. (See Figure below) | 0.4           | 0.4            | 0.4            | 0.4            | 0.4            | V     |
| Maximum overshoot area above VDD (See Figure below)                    | 0.67          | 0.5            | 0.4            | 0.33           | 0.28           | V-ns  |
| Maximum undershoot area below VSS (See Figure below)                   | 0.67          | 0.5            | 0.4            | 0.33           | 0.28           | V-ns  |

(A0-A15, BA0-BA3, CS, RAS, CAS, WE, CKE, ODT)

See figure below for each parameter definition



#### Address and Control Overshoot and Undershoot Definition

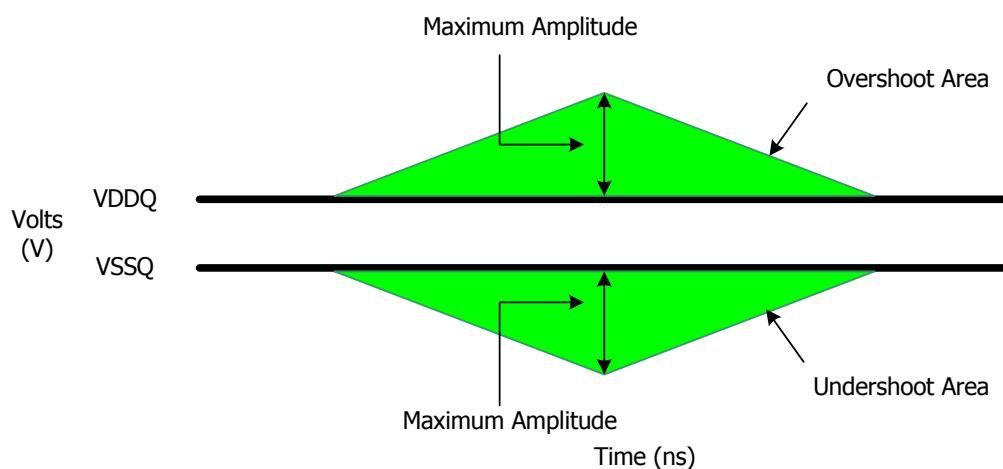
## Clock, Data, Strobe and Mask Overshoot and Undershoot Specifications

### AC Overshoot/Undershoot Specification for Clock, Data, Strobe and Mask

| Parameter                                                              | DDR3  | DDR3   | DDR3   | DDR3   | DDR3   | Units |
|------------------------------------------------------------------------|-------|--------|--------|--------|--------|-------|
|                                                                        | L-800 | L-1066 | L-1333 | L-1600 | L-1866 |       |
| Maximum peak amplitude allowed for overshoot area. (See Figure below)  | 0.4   | 0.4    | 0.4    | 0.4    | 0.4    | V     |
| Maximum peak amplitude allowed for undershoot area. (See Figure below) | 0.4   | 0.4    | 0.4    | 0.4    | 0.4    | V     |
| Maximum overshoot area above VDD (See Figure below)                    | 0.25  | 0.19   | 0.15   | 0.13   | 0.11   | V-ns  |
| Maximum undershoot area below VSS (See Figure below)                   | 0.25  | 0.19   | 0.15   | 0.13   | 0.11   | V-ns  |

(CK,  $\overline{\text{CK}}$ , DQ,  $\overline{\text{DQS}}$ ,  $\overline{\text{DQS}}$ , DM)

See figure below for each parameter definition



### Clock, Data, Strobe and Mask Overshoot and Undershoot Definition

## Refresh parameters by device density

### Refresh parameters by device density

| Parameter                              | RTT_Nom Setting | 512Mb                                                                            | 1Gb | 2Gb | 4Gb | 8Gb | Units |
|----------------------------------------|-----------------|----------------------------------------------------------------------------------|-----|-----|-----|-----|-------|
| REF command ACT or<br>REF command time | tRFC            | 90                                                                               | 110 | 160 | 260 | 350 | ns    |
| Average periodic<br>refresh interval   | tREFI           | $0\text{ }^{\circ}\text{C} \leq T_{\text{CASE}} \leq 85\text{ }^{\circ}\text{C}$ | 7.8 | 7.8 | 7.8 | 7.8 | us    |
|                                        |                 | $85\text{ }^{\circ}\text{C} < T_{\text{CASE}} \leq 95\text{ }^{\circ}\text{C}$   | 3.9 | 3.9 | 3.9 | 3.9 | us    |

#### Notes:

1. Users should refer to the DRAM supplier data sheet and/or the DIMM SPD to determine if DDR3 SDRAM devices support the following options or requirements referred to in this materia.

## Standard Speed Bins

DDR3 SDRAM Standard Speed Bins include tCK, tRCD, tRP, tRAS and tRC for each corresponding bin.

### DDR3L-800 Speed Bins

For specific Notes See "Speed Bin Table Notes" on page 37.

| Speed Bin                                |         |               | DDR3L-800E |           | Unit     | Notes          |
|------------------------------------------|---------|---------------|------------|-----------|----------|----------------|
| CL - nRCD - nRP                          |         |               | 6-6-6      |           |          |                |
| Parameter                                |         | Symbol        | min        | max       |          |                |
| Internal read command to first data      |         | $t_{AA}$      | 15         | 20        | ns       |                |
| ACT to internal read or write delay time |         | $t_{RCD}$     | 15         | —         | ns       |                |
| PRE command period                       |         | $t_{RP}$      | 15         | —         | ns       |                |
| ACT to ACT or REF command period         |         | $t_{RC}$      | 52.5       | —         | ns       |                |
| ACT to PRE command period                |         | $t_{RAS}$     | 37.5       | 9 * tREFI | ns       |                |
| CL = 5                                   | CWL = 5 | $t_{CK(AVG)}$ | 3.0        | 3.3       | ns       | 1, 2, 3, 4, 11 |
| CL = 6                                   | CWL = 5 | $t_{CK(AVG)}$ | 2.5        | 3.3       | ns       | 1, 2, 3        |
| Supported CL Settings                    |         |               | 5, 6       |           | $n_{CK}$ | 10             |
| Supported CWL Settings                   |         |               | 5          |           | $n_{CK}$ |                |

## DDR3L-1066 Speed Bins

For specific Notes See "Speed Bin Table Notes" on page 37.

| Speed Bin                                |           |               | DDR3L-1066F |       | Unit     | Note              |
|------------------------------------------|-----------|---------------|-------------|-------|----------|-------------------|
| CL - nRCD - nRP                          |           |               | 7-7-7       |       |          |                   |
| Parameter                                | Symbol    | min           | max         |       |          |                   |
| Internal read command to first data      | $t_{AA}$  | 13.125        | 20          |       | ns       |                   |
| ACT to internal read or write delay time | $t_{RCD}$ | 13.125        | —           |       | ns       |                   |
| PRE command period                       | $t_{RP}$  | 13.125        | —           |       | ns       |                   |
| ACT to ACT or REF command period         | $t_{RC}$  | 50.625        | —           |       | ns       |                   |
| ACT to PRE command period                | $t_{RAS}$ | 37.5          | 9 * tREFI   |       | ns       |                   |
| CL = 5                                   | CWL = 5   | $t_{CK(AVG)}$ | 3.0         | 3.3   | ns       | 1, 2, 3, 4, 6, 11 |
|                                          | CWL = 6   | $t_{CK(AVG)}$ | Reserved    |       | ns       | 4                 |
| CL = 6                                   | CWL = 5   | $t_{CK(AVG)}$ | 2.5         | 3.3   | ns       | 1, 2, 3, 6        |
|                                          | CWL = 6   | $t_{CK(AVG)}$ | Reserved    |       | ns       | 1, 2, 3, 4        |
| CL = 7                                   | CWL = 5   | $t_{CK(AVG)}$ | Reserved    |       | ns       | 4                 |
|                                          | CWL = 6   | $t_{CK(AVG)}$ | 1.875       | < 2.5 | ns       | 1, 2, 3, 4        |
| CL = 8                                   | CWL = 5   | $t_{CK(AVG)}$ | Reserved    |       | ns       | 4                 |
|                                          | CWL = 6   | $t_{CK(AVG)}$ | 1.875       | < 2.5 | ns       | 1, 2, 3           |
| Supported CL Settings                    |           |               | 5, 6, 7, 8  |       | $n_{CK}$ | 10                |
| Supported CWL Settings                   |           |               | 5, 6        |       | $n_{CK}$ |                   |

## DDR3L-1333 Speed Bins

For specific Notes See "Speed Bin Table Notes" on page 37.

| Speed Bin                                |            |                                  | DDR3L-1333H                |        | Unit     | Note              |
|------------------------------------------|------------|----------------------------------|----------------------------|--------|----------|-------------------|
| CL - nRCD - nRP                          |            |                                  | 9-9-9                      |        |          |                   |
| Parameter                                | Symbol     | min                              | max                        |        |          |                   |
| Internal read command to first data      | $t_{AA}$   | 13.5<br>(13.125) <sup>5,10</sup> | 20                         |        | ns       |                   |
| ACT to internal read or write delay time | $t_{RCD}$  | 13.5<br>(13.125) <sup>5,10</sup> | —                          |        | ns       |                   |
| PRE command period                       | $t_{RP}$   | 13.5<br>(13.125) <sup>5,10</sup> | —                          |        | ns       |                   |
| ACT to ACT or REF command period         | $t_{RC}$   | 49.5<br>(49.125) <sup>5,10</sup> | —                          |        | ns       |                   |
| ACT to PRE command period                | $t_{RAS}$  | 36                               | 9 * tREFI                  |        | ns       |                   |
| CL = 5                                   | CWL = 5    | $t_{CK(AVG)}$                    | 3.0                        | 3.3    | ns       | 1, 2, 3, 4, 7, 11 |
|                                          | CWL = 6, 7 | $t_{CK(AVG)}$                    | Reserved                   |        | ns       | 4                 |
| CL = 6                                   | CWL = 5    | $t_{CK(AVG)}$                    | 2.5                        | 3.3    | ns       | 1, 2, 3, 7        |
|                                          | CWL = 6    | $t_{CK(AVG)}$                    | Reserved                   |        | ns       | 1, 2, 3, 4, 7     |
|                                          | CWL = 7    | $t_{CK(AVG)}$                    | Reserved                   |        | ns       | 4                 |
| CL = 7                                   | CWL = 5    | $t_{CK(AVG)}$                    | Reserved                   |        | ns       | 4                 |
|                                          | CWL = 6    | $t_{CK(AVG)}$                    | 1.875                      | < 2.5  | ns       | 1, 2, 3, 4, 7     |
|                                          |            |                                  | (Optional) <sup>5,10</sup> |        |          |                   |
| CL = 8                                   | CWL = 7    | $t_{CK(AVG)}$                    | Reserved                   |        | ns       | 1, 2, 3, 4        |
|                                          | CWL = 5    | $t_{CK(AVG)}$                    | Reserved                   |        | ns       | 4                 |
|                                          | CWL = 6    | $t_{CK(AVG)}$                    | 1.875                      | < 2.5  | ns       | 1, 2, 3, 7        |
| CL = 9                                   | CWL = 7    | $t_{CK(AVG)}$                    | Reserved                   |        | ns       | 1, 2, 3, 4        |
|                                          | CWL = 5, 6 | $t_{CK(AVG)}$                    | Reserved                   |        | ns       | 4                 |
|                                          | CWL = 7    | $t_{CK(AVG)}$                    | 1.5                        | <1.875 | ns       | 1, 2, 3, 4        |
| CL = 10                                  | CWL = 5, 6 | $t_{CK(AVG)}$                    | Reserved                   |        | ns       | 4                 |
|                                          | CWL = 7    | $t_{CK(AVG)}$                    | 1.5                        | <1.875 | ns       | 1, 2, 3           |
|                                          |            |                                  | (Optional)                 |        | ns       |                   |
| Supported CL Settings                    |            |                                  | 6, (7), 8, 9, 10           |        | $n_{CK}$ |                   |
| Supported CWL Settings                   |            |                                  | 5, 6, 7                    |        | $n_{CK}$ |                   |

## DDR3L-1600 Speed Bins

For specific Notes See "Speed Bin Table Notes" on page 37.

| Speed Bin                                |               |                                   | DDR3L-1600K                |        | Unit     | Note              |
|------------------------------------------|---------------|-----------------------------------|----------------------------|--------|----------|-------------------|
| CL - nRCD - nRP                          |               |                                   | 11-11-11                   |        |          |                   |
| Parameter                                | Symbol        | min                               | max                        |        |          |                   |
| Internal read command to first data      | $t_{AA}$      | 13.75<br>(13.125) <sup>5,10</sup> | 20                         |        | ns       |                   |
| ACT to internal read or write delay time | $t_{RCD}$     | 13.75<br>(13.125) <sup>5,10</sup> | —                          |        | ns       |                   |
| PRE command period                       | $t_{RP}$      | 13.75<br>(13.125) <sup>5,10</sup> | —                          |        | ns       |                   |
| ACT to ACT or REF command period         | $t_{RC}$      | 48.75<br>(48.125) <sup>5,10</sup> | —                          |        | ns       |                   |
| ACT to PRE command period                | $t_{RAS}$     | 35                                | 9 * tREFI                  |        | ns       |                   |
| CL = 5                                   | CWL = 5       | $t_{CK(AVG)}$                     | 3.0                        | 3.3    | ns       | 1, 2, 3, 4, 8, 11 |
|                                          | CWL = 6, 7    | $t_{CK(AVG)}$                     | Reserved                   |        | ns       | 4                 |
| CL = 6                                   | CWL = 5       | $t_{CK(AVG)}$                     | 2.5                        | 3.3    | ns       | 1, 2, 3, 8        |
|                                          | CWL = 6       | $t_{CK(AVG)}$                     | Reserved                   |        | ns       | 1, 2, 3, 4, 8     |
|                                          | CWL = 7       | $t_{CK(AVG)}$                     | Reserved                   |        | ns       | 4                 |
| CL = 7                                   | CWL = 5       | $t_{CK(AVG)}$                     | Reserved                   |        | ns       | 4                 |
|                                          | CWL = 6       | $t_{CK(AVG)}$                     | 1.875                      | < 2.5  | ns       | 1, 2, 3, 4, 8     |
|                                          |               |                                   | (Optional) <sup>5,10</sup> |        |          |                   |
|                                          | CWL = 7       | $t_{CK(AVG)}$                     | Reserved                   |        | ns       | 1, 2, 3, 4, 8     |
|                                          | CWL = 8       | $t_{CK(AVG)}$                     | Reserved                   |        | ns       | 4                 |
| CL = 8                                   | CWL = 5       | $t_{CK(AVG)}$                     | Reserved                   |        | ns       | 4                 |
|                                          | CWL = 6       | $t_{CK(AVG)}$                     | 1.875                      | < 2.5  | ns       | 1, 2, 3, 8        |
|                                          | CWL = 7       | $t_{CK(AVG)}$                     | Reserved                   |        | ns       | 1, 2, 3, 4, 8     |
|                                          | CWL = 8       | $t_{CK(AVG)}$                     | Reserved                   |        | ns       | 1, 2, 3, 4        |
| CL = 9                                   | CWL = 5, 6    | $t_{CK(AVG)}$                     | Reserved                   |        | ns       | 4                 |
|                                          | CWL = 7       | $t_{CK(AVG)}$                     | 1.5                        | <1.875 | ns       | 1, 2, 3, 4, 8     |
|                                          |               |                                   | (Optional) <sup>5,10</sup> |        |          |                   |
|                                          | CWL = 8       | $t_{CK(AVG)}$                     | Reserved                   |        | ns       | 1, 2, 3, 4        |
| CL = 10                                  | CWL = 5, 6    | $t_{CK(AVG)}$                     | Reserved                   |        | ns       | 4                 |
|                                          | CWL = 7       | $t_{CK(AVG)}$                     | 1.5                        | <1.875 | ns       | 1, 2, 3, 8        |
|                                          | CWL = 8       | $t_{CK(AVG)}$                     | Reserved                   |        | ns       | 1, 2, 3, 4        |
| CL = 11                                  | CWL = 5, 6, 7 | $t_{CK(AVG)}$                     | Reserved                   |        | ns       | 4                 |
|                                          | CWL = 8       | $t_{CK(AVG)}$                     | 1.25                       | <1.5   | ns       | 1, 2, 3           |
| Supported CL Settings                    |               |                                   | 5, 6, (7), 8, (9), 10, 11  |        | $n_{CK}$ |                   |
| Supported CWL Settings                   |               |                                   | 5, 6, 7, 8                 |        | $n_{CK}$ |                   |

## DDR3L-1866 Speed Bins

For specific Notes See "Speed Bin Table Notes" on page 37.

| Speed Bin                                |               |                                   | DDR3L-1866M           |          | Unit     | Note          |
|------------------------------------------|---------------|-----------------------------------|-----------------------|----------|----------|---------------|
| CL - nRCD - nRP                          |               |                                   | 13-13-13              |          |          |               |
| Parameter                                | Symbol        | min                               | max                   |          |          |               |
| Internal read command to first data      | $t_{AA}$      | 13.91<br>(13.125) <sup>5,12</sup> | 20                    |          | ns       |               |
| ACT to internal read or write delay time | $t_{RCD}$     | 13.91<br>(13.125) <sup>5,12</sup> | —                     |          | ns       |               |
| PRE command period                       | $t_{RP}$      | 13.91<br>(13.125) <sup>5,12</sup> | —                     |          | ns       |               |
| ACT to PRE command period                | $t_{RAS}$     | 34                                | 9 * tREFI             |          | ns       |               |
| ACT to ACT or PRE command period         | $t_{RC}$      | 47.91<br>(47.125) <sup>5,12</sup> | -                     |          | ns       |               |
| CL = 5                                   | CWL = 5       | $t_{CK(AVG)}$                     | 3.0                   | 3.3      | ns       | 1, 2, 3, 4, 9 |
|                                          | CWL = 6,7,8,9 | $t_{CK(AVG)}$                     | Reserved              |          | ns       | 4             |
| CL = 6                                   | CWL = 5       | $t_{CK(AVG)}$                     | 2.5                   | 3.3      | ns       | 1, 2, 3, 9    |
|                                          | CWL = 6       | $t_{CK(AVG)}$                     | Reserved              |          | ns       | 1, 2, 3, 4, 9 |
|                                          | CWL = 7,8,9   | $t_{CK(AVG)}$                     | Reserved              |          | ns       | 4             |
| CL = 7                                   | CWL = 5       | $t_{CK(AVG)}$                     | Reserved              |          | ns       | 4             |
|                                          | CWL = 6       | $t_{CK(AVG)}$                     | 1.875                 | < 2.5    | ns       | 1, 2, 3, 4, 9 |
|                                          |               |                                   | (Optimal)             |          |          |               |
|                                          | CWL = 7,8,9   | $t_{CK(AVG)}$                     | Reserved              |          | ns       | 4             |
| CL = 8                                   | CWL = 5       | $t_{CK(AVG)}$                     | Reserved              |          | ns       | 4             |
|                                          | CWL = 6       | $t_{CK(AVG)}$                     | 1.875                 | < 2.5    | ns       | 1, 2, 3, 9    |
|                                          | CWL = 7       | $t_{CK(AVG)}$                     | Reserved              |          | ns       | 1, 2, 3, 4, 9 |
|                                          | CWL = 8,9     | $t_{CK(AVG)}$                     | Reserved              |          | ns       | 4             |
| CL = 9                                   | CWL = 5, 6    | $t_{CK(AVG)}$                     | Reserved              |          | ns       | 4             |
|                                          | CWL = 7       | $t_{CK(AVG)}$                     | 1.5                   | <1.875   | ns       | 1, 2, 3, 4, 9 |
|                                          |               |                                   | (Optimal)             |          |          |               |
|                                          |               | CWL = 8                           | $t_{CK(AVG)}$         | Reserved |          | ns            |
|                                          | CWL = 9       | $t_{CK(AVG)}$                     | Reserved              |          | ns       | 4             |
| CL = 10                                  | CWL = 5, 6    | $t_{CK(AVG)}$                     | Reserved              |          | ns       | 4             |
|                                          | CWL = 7       | $t_{CK(AVG)}$                     | 1.5                   | <1.875   | ns       | 1, 2, 3, 9    |
|                                          | CWL = 8       | $t_{CK(AVG)}$                     | Reserved              |          | ns       | 1, 2, 3, 4, 9 |
| CL = 11                                  | CWL = 5,6,7   | $t_{CK(AVG)}$                     | Reserved              |          | ns       | 4             |
|                                          | CWL = 8       | $t_{CK(AVG)}$                     | 1.25                  | <1.5     | ns       | 1, 2, 3, 4, 9 |
|                                          |               |                                   | (Optimal)             |          |          |               |
|                                          |               | CWL = 9                           | $t_{CK(AVG)}$         | Reserved |          | ns            |
| CL = 12                                  | CWL = 5,6,7,8 | $t_{CK(AVG)}$                     | Reserved              |          | ns       | 4             |
|                                          | CWL = 9       | $t_{CK(AVG)}$                     | Reserved              |          | ns       | 1,2,3,4       |
| CL = 13                                  | CWL = 5,6,7,8 | $t_{CK(AVG)}$                     | Reserved              |          | ns       | 4             |
|                                          | CWL = 9       | $t_{CK(AVG)}$                     | 1.07                  | <1.25    | ns       | 1, 2, 3       |
| Supported CL Settings                    |               |                                   | 6, 7, 8, 9, 10, 11,13 |          | $n_{CK}$ |               |
| Supported CWL Settings                   |               |                                   | 5, 6, 7, 8, 9         |          | $n_{CK}$ |               |

## Speed Bin Table Notes

Absolute Specification ( $T_{\text{OPER}}$ ;  $V_{\text{DDQ}} = V_{\text{DD}} = 1.35\text{V} + 0.100/-0.067\text{V}$ );

1. The CL setting and CWL setting result in  $t_{\text{CK}}(\text{AVG})_{\text{MIN}}$  and  $t_{\text{CK}}(\text{AVG})_{\text{MAX}}$  requirements. When making a selection of  $t_{\text{CK}}(\text{AVG})$ , both need to be fulfilled: Requirements from CL setting as well as requirements from CWL setting.
2.  $t_{\text{CK}}(\text{AVG})_{\text{MIN}}$  limits: Since CAS Latency is not purely analog - data and strobe output are synchronized by the DLL - all possible intermediate frequencies may not be guaranteed. An application should use the next smaller JEDEC standard  $t_{\text{CK}}(\text{AVG})$  value (3.0, 2.5, 1.875, 1.5, or 1.25 ns) when calculating  $\text{CL} [\text{nCK}] = t_{\text{AA}} [\text{ns}] / t_{\text{CK}}(\text{AVG}) [\text{ns}]$ , rounding up to the next 'Supported CL', where  $t_{\text{CK}}(\text{AVG}) = 3.0\text{ ns}$  should only be used for  $\text{CL} = 5$  calculation.
3.  $t_{\text{CK}}(\text{AVG})_{\text{MAX}}$  limits: Calculate  $t_{\text{CK}}(\text{AVG}) = t_{\text{AA}}_{\text{MAX}} / \text{CL SELECTED}$  and round the resulting  $t_{\text{CK}}(\text{AVG})$  down to the next valid speed bin (i.e. 3.3ns or 2.5ns or 1.875 ns or 1.25 ns). This result is  $t_{\text{CK}}(\text{AVG})_{\text{MAX}}$  corresponding to CL SELECTED.
4. 'Reserved' settings are not allowed. User must program a different value.
5. 'Optional' settings allow certain devices in the industry to support this setting, however, it is not a mandatory feature. Refer to DIMM data sheet and/or the DIMM SPD information if and how this setting is supported.
6. Any DDR3-1066 speed bin also supports functional operation at lower frequencies as shown in the table which are not subject to Production Tests but verified by Design/Characterization.
7. Any DDR3-1333 speed bin also supports functional operation at lower frequencies as shown in the table which are not subject to Production Tests but verified by Design/Characterization.
8. Any DDR3-1600 speed bin also supports functional operation at lower frequencies as shown in the table which are not subject to Production Tests but verified by Design/Characterization.
9. Any DDR3-1866 speed bin also supports functional operation at lower frequencies as shown in the table which are not subject to Production Tests but verified by Design/Characterization.
10. DDR3 SDRAM devices supporting optional down binning to  $\text{CL}=7$  and  $\text{CL}=9$ , and  $t_{\text{AA}}/t_{\text{RCD}}/t_{\text{RP}}$  must be 13.125 ns or lower. SPD settings must be programmed to match. For example, DDR3-1333H devices supporting down binning to DDR3-1066F should program 13.125 ns in SPD bytes for  $t_{\text{AAmin}}$  (Byte 16),  $t_{\text{RCDmin}}$  (Byte 18), and  $t_{\text{RPmin}}$  (Byte 20). DDR3-1600K devices supporting down binning to DDR3-1333H or DDR3-1600F should program 13.125 ns in SPD bytes for  $t_{\text{AAmin}}$  (Byte 16),  $t_{\text{RCDmin}}$  (Byte 18), and  $t_{\text{RPmin}}$  (Byte 20). Once  $t_{\text{RP}}$  (Byte 20) is programmed to 13.125ns,  $t_{\text{RCmin}}$  (Byte 21,23) also should be programmed accordingly. For example, 49.125ns ( $t_{\text{RASmin}} + t_{\text{RPmin}} = 36\text{ ns} + 13.125\text{ ns}$ ) for DDR3-1333H and 48.125ns ( $t_{\text{RASmin}} + t_{\text{RPmin}} = 35\text{ ns} + 13.125\text{ ns}$ ) for DDR3-1600K.
11. For CL5 support, refer to DIMM SPD information. DRAM is required to support CL5. CL5 is not mandatory in SPD coding.
12. DDR3 SDRAM devices supporting optional down binning to  $\text{CL}=11$ ,  $\text{CL}=9$  and  $\text{CL}=7$ ,  $t_{\text{AA}}/t_{\text{RCD}}/t_{\text{RPmin}}$  must be 13.125ns. SPD setting must be programmed to match. For example, DDR3-1866M devices supporting down binning to DDR3-1600K or DDR3-1333H or 1066F should program 13.125ns in SPD bytes for  $t_{\text{AAmin}}$ (byte16),  $t_{\text{RCDmin}}$ (byte18) and  $t_{\text{RPmin}}$ (byte20). Once  $t_{\text{RP}}$  (byte20) is programmed to 13.125ns,  $t_{\text{RCmin}}$ (byte 21,23) also should be programmed accordingly. For example, 47.125ns( $t_{\text{RASmin}} + t_{\text{RPmin}} = 34\text{ns} + 13.125\text{ns}$ )

## Environmental Parameters

| Symbol           | Parameter                                 | Rating      | Units    | Notes |
|------------------|-------------------------------------------|-------------|----------|-------|
| T <sub>OPR</sub> | Operating temperature                     | 0 to 65     | °C       | 1, 3  |
| H <sub>OPR</sub> | Operating humidity (relative)             | 10 to 90    | %        | 1     |
| T <sub>STG</sub> | Storage temperature                       | -50 to +100 | °C       | 1     |
| H <sub>STG</sub> | Storage humidity (without condensation)   | 5 to 95     | %        | 1     |
| P <sub>BAR</sub> | Barometric Pressure (operating & storage) | 105 to 69   | K Pascal | 1, 2  |

**Note:**

1. Stress greater than those listed may cause permanent damage to the device. This is a stress rating only, and device functional operation at or above the conditions indicated is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
2. Up to 9850 ft.
3. The designer must meet the case temperature specifications for individual module components.

## IDD and IDDQ Specification Parameters and Test Conditions

### IDD and IDDQ Measurement Conditions

In this chapter, IDD and IDDQ measurement conditions such as test load and patterns are defined. Figure 1. shows the setup and test load for IDD and IDDQ measurements.

- IDD currents (such as IDD0, IDD1, IDD2N, IDD2NT, IDD2P0, IDD2P1, IDD2Q, IDD3N, IDD3P, IDD4R, IDD4W, IDD5B, IDD6, IDD6ET and IDD7) are measured as time-averaged currents with all VDD balls of the DDR3L SDRAM under test tied together. Any IDDQ current is not included in IDD currents.
- IDDQ currents (such as IDDQ2NT and IDDQ4R) are measured as time-averaged currents with all VDDQ balls of the DDR3L SDRAM under test tied together. Any IDD current is not included in IDDQ currents.

Attention: IDDQ values cannot be directly used to calculate IO power of the DDR3L SDRAM. They can be used to support correlation of simulated IO power to actual IO power as outlined in Figure 2. In DRAM module application, IDDQ cannot be measured separately since VDD and VDDQ are using one merged-power layer in Module PCB.

For IDD and IDDQ measurements, the following definitions apply:

- "0" and "LOW" is defined as  $V_{IN} \leq V_{ILAC(max)}$ .
- "1" and "HIGH" is defined as  $V_{IN} \geq V_{IHAC(max)}$ .
- "MID\_LEVEL" is defined as inputs are  $V_{REF} = V_{DD}/2$ .
- Timing used for IDD and IDDQ Measurement-Loop Patterns are provided in Table 1.
- Basic IDD and IDDQ Measurement Conditions are described in Table 2.
- Detailed IDD and IDDQ Measurement-Loop Patterns are described in Table 3 through Table 10.
- IDD Measurements are done after properly initializing the DDR3L SDRAM. This includes but is not limited to setting  
 $R_{ON} = R_{ZQ}/7$  (34 Ohm in MR1);  
 $Q_{off} = 0_B$  (Output Buffer enabled in MR1);  
 $R_{TT\_Nom} = R_{ZQ}/6$  (40 Ohm in MR1);  
 $R_{TT\_Wr} = R_{ZQ}/2$  (120 Ohm in MR2);  
 TDQS Feature disabled in MR1
- Attention: The IDD and IDDQ Measurement-Loop Patterns need to be executed at least one time before actual IDD or IDDQ measurement is started.
- Define  $D = \{\overline{CS}, \overline{RAS}, \overline{CAS}, \overline{WE}\} := \{HIGH, LOW, LOW, LOW\}$
- Define  $\overline{D} = \{\overline{CS}, \overline{RAS}, \overline{CAS}, \overline{WE}\} := \{HIGH, HIGH, HIGH, HIGH\}$

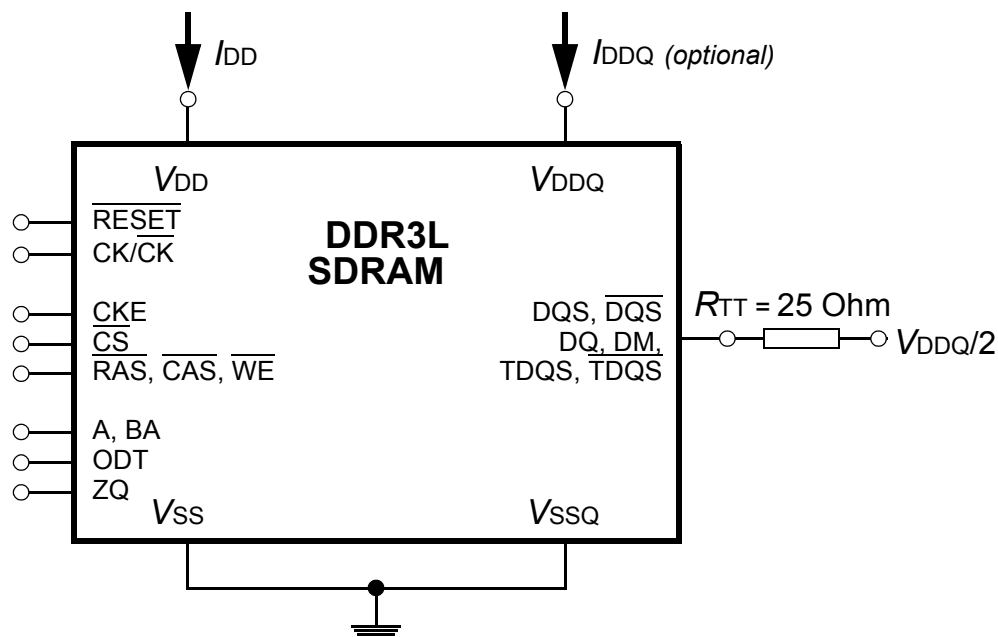


Figure 1 - Measurement Setup and Test Load for IDD and IDDQ (optional) Measurements  
[Note: DIMM level Output test load condition may be different from above]

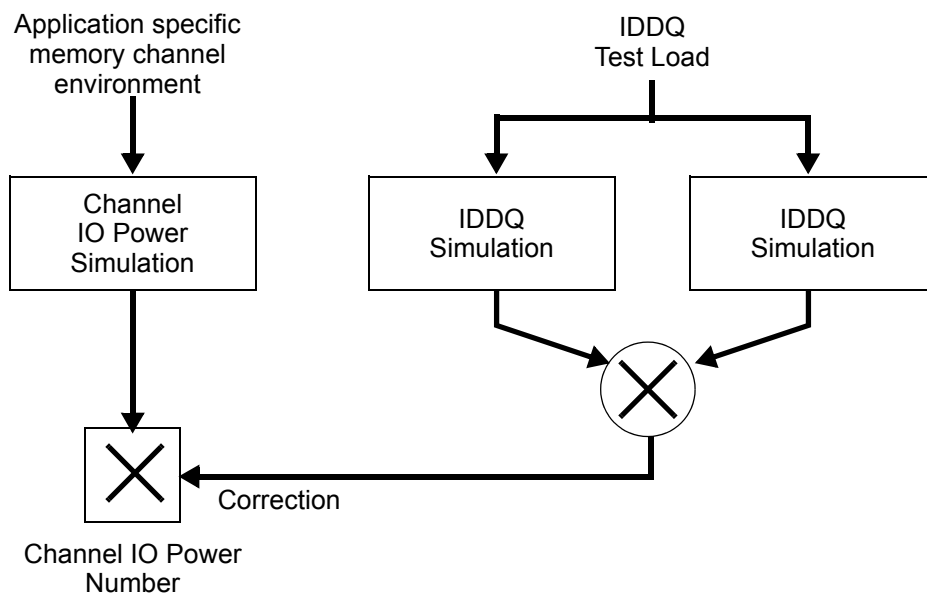


Figure 2 - Correlation from simulated Channel IO Power to actual Channel IO Power supported by IDDQ Measurement

**Table 1 -Timings used for IDD and IDDQ Measurement-Loop Patterns**

| Symbol           |               | DDR3L-1066 | DDR3L-1333 | DDR3L-1600 | DDR3L-1866 | Unit |
|------------------|---------------|------------|------------|------------|------------|------|
|                  |               | 7-7-7      | 9-9-9      | 11-11-11   | 13-13-13   |      |
| $t_{CK}$         |               | 1.875      | 1.5        | 1.25       | 1.07       | ns   |
| CL               |               | 7          | 9          | 11         | 13         | nCK  |
| $t_{RCD}$        |               | 7          | 9          | 11         | 13         | nCK  |
| $t_{RC}$         |               | 27         | 33         | 39         | 45         | nCK  |
| $t_{RAS}$        |               | 20         | 24         | 28         | 32         | nCK  |
| $t_{RP}$         |               | 7          | 9          | 11         | 13         | nCK  |
| $t_{FAW}$        | 1KB page size | 20         | 20         | 24         | 26         | nCK  |
|                  | 2KB page size | 27         | 30         | 32         | 33         | nCK  |
| $t_{RRD}$        | 1KB page size | 4          | 4          | 5          | 5          | nCK  |
|                  | 2KB page size | 6          | 5          | 6          | 6          | nCK  |
| $t_{RFC}$ -512Mb |               | 48         | 60         | 72         | 85         | nCK  |
| $t_{RFC}$ -1 Gb  |               | 59         | 74         | 88         | 103        | nCK  |
| $t_{RFC}$ -2 Gb  |               | 86         | 107        | 128        | 150        | nCK  |
| $t_{RFC}$ -4 Gb  |               | 139        | 174        | 208        | 243        | nCK  |
| $t_{RFC}$ -8 Gb  |               | 187        | 234        | 280        | 328        | nCK  |

**Table 2 -Basic IDD and IDDQ Measurement Conditions**

| Symbol    | Description                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                |
|-----------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| $I_{DD0}$ | Operating One Bank Active-Precharge Current<br>CKE: High; External clock: On; tCK, nRC, nRAS, CL: see Table 1; BL: 8 <sup>a</sup> ); AL: 0; $\overline{CS}$ : High between ACT and PRE; Command, Address, Bank Address Inputs: partially toggling according to Table 3; Data IO: MID-LEVEL; DM: stable at 0; Bank Activity: Cycling with one bank active at a time: 0,0,1,1,2,2,... (see Table 3); Output Buffer and RTT: Enabled in Mode Registers <sup>b</sup> ); ODT Signal: stable at 0; Pattern Details: see Table 3. |
| $I_{DD1}$ | Operating One Bank Active-Precharge Current<br>CKE: High; External clock: On; tCK, nRC, nRAS, nRCD, CL: see Table 1; BL: 8 <sup>a</sup> ); AL: 0; $\overline{CS}$ : High between ACT, RD and PRE; Command, Address; Bank Address Inputs, Data IO: partially toggling according to Table 4; DM: stable at 0; Bank Activity: Cycling with on bank active at a time: 0,0,1,1,2,2,... (see Table 4); Output Buffer and RTT: Enabled in Mode Registers <sup>b</sup> ); ODT Signal: stable at 0; Pattern Details: see Table 4.   |

| Symbol      | Description                                                                                                                                                                                                                                                                                                                                                                                                                                       |
|-------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| $I_{DD2N}$  | Precharge Standby Current<br>CKE: High; External clock: On; tCK, CL: see Table 1; BL: 8 <sup>a)</sup> ; AL: 0; $\overline{CS}$ : stable at 1; Command, Address, Bank Address Inputs: partially toggling according to Table 5; Data IO: MID_LEVEL; DM: stable at 0; Bank Activity: all banks closed; Output Buffer and RTT: Enabled in Mode Registers <sup>b)</sup> ; ODT Signal: stable at 0; Pattern Details: see Table 5.                       |
| $I_{DD2NT}$ | Precharge Standby ODT Current<br>CKE: High; External clock: On; tCK, CL: see Table 1; BL: 8 <sup>a)</sup> ; AL: 0; $\overline{CS}$ : stable at 1; Command, Address, Bank Address Inputs: partially toggling according to Table 6; Data IO: MID_LEVEL; DM: stable at 0; Bank Activity: all banks closed; Output Buffer and RTT: Enabled in Mode Registers <sup>b)</sup> ; ODT Signal: toggling according to Table 6; Pattern Details: see Table 6. |
| $I_{DD2P0}$ | Precharge Power-Down Current Slow Exit<br>CKE: Low; External clock: On; tCK, CL: see Table 1; BL: 8 <sup>a)</sup> ; AL: 0; $\overline{CS}$ : stable at 1; Command, Address, Bank Address Inputs: stable at 0; Data IO: MID_LEVEL; DM: stable at 0; Bank Activity: all banks closed; Output Buffer and RTT: Enabled in Mode Registers <sup>b)</sup> ; ODT Signal: stable at 0; Precharge Power Down Mode: Slow Exit <sup>c)</sup>                  |
| $I_{DD2P1}$ | Precharge Power-Down Current Fast Exit<br>CKE: Low; External clock: On; tCK, CL: see Table 1; BL: 8 <sup>a)</sup> ; AL: 0; $\overline{CS}$ : stable at 1; Command, Address, Bank Address Inputs: stable at 0; Data IO: MID_LEVEL; DM: stable at 0; Bank Activity: all banks closed; Output Buffer and RTT: Enabled in Mode Registers <sup>b)</sup> ; ODT Signal: stable at 0; Precharge Power Down Mode: Fast Exit <sup>c)</sup>                  |
| $I_{DD2Q}$  | Precharge Quiet Standby Current<br>CKE: High; External clock: On; tCK, CL: see Table 1; BL: 8 <sup>a)</sup> ; AL: 0; $\overline{CS}$ : stable at 1; Command, Address, Bank Address Inputs: stable at 0; Data IO: MID_LEVEL; DM: stable at 0; Bank Activity: all banks closed; Output Buffer and RTT: Enabled in Mode Registers <sup>b)</sup> ; ODT Signal: stable at 0                                                                            |
| $I_{DD3N}$  | Active Standby Current<br>CKE: High; External clock: On; tCK, CL: see Table 1; BL: 8 <sup>a)</sup> ; AL: 0; $\overline{CS}$ : stable at 1; Command, Address, Bank Address Inputs: partially toggling according to Table 5; Data IO: MID_LEVEL; DM: stable at 0; Bank Activity: all banks open; Output Buffer and RTT: Enabled in Mode Registers <sup>b)</sup> ; ODT Signal: stable at 0; Pattern Details: see Table 5.                            |
| $I_{DD3P}$  | Active Power-Down Current<br>CKE: Low; External clock: On; tCK, CL: see Table 1; BL: 8 <sup>a)</sup> ; AL: 0; $\overline{CS}$ : stable at 1; Command, Address, Bank Address Inputs: stable at 0; Data IO: MID_LEVEL; DM: stable at 0; Bank Activity: all banks open; Output Buffer and RTT: Enabled in Mode Registers <sup>b)</sup> ; ODT Signal: stable at 0                                                                                     |

| Symbol      | Description                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                       |
|-------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| $I_{DD4R}$  | <p>Operating Burst Read Current</p> <p>CKE: High; External clock: On; tCK, CL: see Table 1; BL: 8<sup>a</sup>); AL: 0; <math>\overline{CS}</math>: High between RD; Command, Address, Bank Address Inputs: partially toggling according to Table 7; Data IO: seamless read data burst with different data between one burst and the next one according to Table 7; DM: stable at 0; Bank Activity: all banks open, RD commands cycling through banks: 0,0,1,1,2,2,...(see Table 7); Output Buffer and RTT: Enabled in Mode Registers<sup>b</sup>); ODT Signal: stable at 0; Pattern Details: see Table 7.</p>     |
| $I_{DD4W}$  | <p>Operating Burst Write Current</p> <p>CKE: High; External clock: On; tCK, CL: see Table 1; BL: 8<sup>a</sup>); AL: 0; <math>\overline{CS}</math>: High between WR; Command, Address, Bank Address Inputs: partially toggling according to Table 8; Data IO: seamless read data burst with different data between one burst and the next one according to Table 8; DM: stable at 0; Bank Activity: all banks open, WR commands cycling through banks: 0,0,1,1,2,2,...(see Table 8); Output Buffer and RTT: Enabled in Mode Registers<sup>b</sup>); ODT Signal: stable at HIGH; Pattern Details: see Table 8.</p> |
| $I_{DD5B}$  | <p>Burst Refresh Current</p> <p>CKE: High; External clock: On; tCK, CL, nRFC: see Table 1; BL: 8<sup>a</sup>); AL: 0; <math>\overline{CS}</math>: High between REF; Command, Address, Bank Address Inputs: partially toggling according to Table 9; Data IO: MID_LEVEL; DM: stable at 0; Bank Activity: REF command every nREF (see Table 9); Output Buffer and RTT: Enabled in Mode Registers<sup>b</sup>); ODT Signal: stable at 0; Pattern Details: see Table 9.</p>                                                                                                                                           |
| $I_{DD6}$   | <p>Self-Refresh Current: Normal Temperature Range</p> <p><math>T_{CASE}</math>: 0 - 85 °C; Auto Self-Refresh (ASR): Disabled<sup>d</sup>); Self-Refresh Temperature Range (SRT): Normal<sup>e</sup>); CKE: Low; External clock: Off; CK and <math>\overline{CK}</math>: LOW; CL: see Table 1; BL: 8<sup>a</sup>); AL: 0; <math>\overline{CS}</math>, Command, Address, Bank Address Inputs, Data IO: MID_LEVEL; DM: stable at 0; Bank Activity: Self-Refresh operation; Output Buffer and RTT: Enabled in Mode Registers<sup>b</sup>); ODT Signal: MID_LEVEL</p>                                                  |
| $I_{DD6ET}$ | <p>Self-Refresh Current: Extended Temperature Range</p> <p><math>T_{CASE}</math>: 0 - 95 °C; Auto Self-Refresh (ASR): Disabled<sup>d</sup>); Self-Refresh Temperature Range (SRT): Extended<sup>e</sup>); CKE: Low; External clock: Off; CK and <math>\overline{CK}</math>: LOW; CL: see Table 1; BL: 8<sup>a</sup>); AL: 0; <math>\overline{CS}</math>, Command, Address, Bank Address Inputs, Data IO: MID_LEVEL; DM: stable at 0; Bank Activity: Extended Temperature Self-Refresh operation; Output Buffer and RTT: Enabled in Mode Registers<sup>b</sup>); ODT Signal: MID_LEVEL</p>                         |

| Symbol    | Description                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                  |
|-----------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| $I_{DD7}$ | <p>Operating Bank Interleave Read Current</p> <p>CKE: High; External clock: On; tCK, nRC, nRAS, nRCD, NRRD, nFAW, CL: see Table 1; BL: 8<sup>a,f)</sup>; AL: CL-1; <math>\overline{CS}</math>: High between ACT and RDA; Command, Address, Bank Address Inputs: partially toggling according to Table 10; Data IO: read data burst with different data between one burst and the next one according to Table 10; DM: stable at 0; Bank Activity: two times interleaved cycling through banks (0, 1,...7) with different addressing, see Table 10; Output Buffer and RTT: Enabled in Mode Registers<sup>b)</sup>; ODT Signal: stable at 0; Pattern Details: see Table 10.</p> |

a) Burst Length: BL8 fixed by MRS: set MR0 A[1,0]=00B

b) Output Buffer Enable: set MR1 A[12] = 0B; set MR1 A[5,1] = 01B; RTT\_Nom enable: set MR1 A[9,6,2] = 011B; RTT\_Wr enable: set MR2 A[10,9] = 10B

c) Precharge Power Down Mode: set MR0 A12=0B for Slow Exit or MR0 A12 = 1B for Fast Exit

d) Auto Self-Refresh (ASR): set MR2 A6 = 0B to disable

e) Self-Refresh Temperature Range (SRT): set MR2 A7 = 0B for normal or 1B for extended temperature range

f) Read Burst Type: Nibble Sequential, set MR0 A[3] = 0B

**Table 3 - IDD0 Measurement-Loop Pattern<sup>a)</sup>**

| CK, CK   | CKE         | Sub-Loop | Cycle Number | Command                                                            | $\overline{CS}$ | $\overline{RAS}$ | $\overline{CAS}$ | $\overline{WE}$ | ODT | BA[2:0] | A[15:11] | A[10] | A[9:7] | A[6:3] | A[2:0] | Data <sup>b)</sup> |
|----------|-------------|----------|--------------|--------------------------------------------------------------------|-----------------|------------------|------------------|-----------------|-----|---------|----------|-------|--------|--------|--------|--------------------|
| toggling | Static High | 0        | 0            | ACT                                                                | 0               | 0                | 1                | 1               | 0   | 0       | 00       | 0     | 0      | 0      | 0      | -                  |
|          |             |          | 1,2          | D, D                                                               | 1               | 0                | 0                | 0               | 0   | 0       | 00       | 0     | 0      | 0      | 0      | -                  |
|          |             |          | 3,4          | $\overline{D}$ , $\overline{D}$                                    | 1               | 1                | 1                | 1               | 0   | 0       | 00       | 0     | 0      | 0      | 0      | -                  |
|          |             |          | ...          | repeat pattern 1...4 until nRAS - 1, truncate if necessary         |                 |                  |                  |                 |     |         |          |       |        |        |        |                    |
|          |             |          | nRAS         | PRE                                                                | 0               | 0                | 1                | 0               | 0   | 0       | 00       | 0     | 0      | 0      | 0      | -                  |
|          |             |          | ...          | repeat pattern 1...4 until nRC - 1, truncate if necessary          |                 |                  |                  |                 |     |         |          |       |        |        |        |                    |
|          |             |          | 1*nRC+0      | ACT                                                                | 0               | 0                | 1                | 1               | 0   | 0       | 00       | 0     | 0      | F      | 0      | -                  |
|          |             |          | 1*nRC+1, 2   | D, D                                                               | 1               | 0                | 0                | 0               | 0   | 0       | 00       | 0     | 0      | F      | 0      | -                  |
|          |             |          | 1*nRC+3, 4   | $\overline{D}$ , $\overline{D}$                                    | 1               | 1                | 1                | 1               | 0   | 0       | 00       | 0     | 0      | F      | 0      | -                  |
|          |             |          | ...          | repeat pattern 1...4 until 1*nRC + nRAS - 1, truncate if necessary |                 |                  |                  |                 |     |         |          |       |        |        |        |                    |
|          |             |          | 1*nRC+nRAS   | PRE                                                                | 0               | 0                | 1                | 0               | 0   | 0       | 00       | 0     | 0      | F      | 0      | -                  |
|          |             |          | ...          | repeat pattern 1...4 until 2*nRC - 1, truncate if necessary        |                 |                  |                  |                 |     |         |          |       |        |        |        |                    |
|          |             | 1        | 2*nRC        | repeat Sub-Loop 0, use BA[2:0] = 1 instead                         |                 |                  |                  |                 |     |         |          |       |        |        |        |                    |
|          |             | 2        | 4*nRC        | repeat Sub-Loop 0, use BA[2:0] = 2 instead                         |                 |                  |                  |                 |     |         |          |       |        |        |        |                    |
|          |             | 3        | 6*nRC        | repeat Sub-Loop 0, use BA[2:0] = 3 instead                         |                 |                  |                  |                 |     |         |          |       |        |        |        |                    |
|          |             | 4        | 8*nRC        | repeat Sub-Loop 0, use BA[2:0] = 4 instead                         |                 |                  |                  |                 |     |         |          |       |        |        |        |                    |
|          |             | 5        | 10*nRC       | repeat Sub-Loop 0, use BA[2:0] = 5 instead                         |                 |                  |                  |                 |     |         |          |       |        |        |        |                    |
|          |             | 6        | 12*nRC       | repeat Sub-Loop 0, use BA[2:0] = 6 instead                         |                 |                  |                  |                 |     |         |          |       |        |        |        |                    |
|          |             | 7        | 14*nRC       | repeat Sub-Loop 0, use BA[2:0] = 7 instead                         |                 |                  |                  |                 |     |         |          |       |        |        |        |                    |

a) DM must be driven LOW all the time. DQS,  $\overline{DQS}$  are MID-LEVEL.

b) DQ signals are MID-LEVEL.

**Table 4 - IDD1 Measurement-Loop Pattern<sup>a)</sup>**

| CK, $\overline{\text{CK}}$ | CKE         | Sub-Loop | Cycle Number | Command                                                                 | $\overline{\text{CS}}$ | $\overline{\text{RAS}}$ | $\overline{\text{CAS}}$ | $\overline{\text{WE}}$ | ODT | BA[2:0] | A[15:11] | A[10] | A[9:7] | A[6:3] | A[2:0] | Data <sup>b)</sup> |
|----------------------------|-------------|----------|--------------|-------------------------------------------------------------------------|------------------------|-------------------------|-------------------------|------------------------|-----|---------|----------|-------|--------|--------|--------|--------------------|
| toggling                   | Static High | 0        | 0            | ACT                                                                     | 0                      | 0                       | 1                       | 1                      | 0   | 0       | 00       | 0     | 0      | 0      | 0      | -                  |
|                            |             |          | 1,2          | D, D                                                                    | 1                      | 0                       | 0                       | 0                      | 0   | 0       | 00       | 0     | 0      | 0      | 0      | -                  |
|                            |             |          | 3,4          | $\overline{\text{D}}, \overline{\text{D}}$                              | 1                      | 1                       | 1                       | 1                      | 0   | 0       | 00       | 0     | 0      | 0      | 0      | -                  |
|                            |             |          | ...          | repeat pattern 1...4 until nRCD - 1, truncate if necessary              |                        |                         |                         |                        |     |         |          |       |        |        |        |                    |
|                            |             |          | nRCD         | RD                                                                      | 0                      | 1                       | 0                       | 1                      | 0   | 0       | 00       | 0     | 0      | 0      | 0      | 00000000           |
|                            |             |          | ...          | repeat pattern 1...4 until nRAS - 1, truncate if necessary              |                        |                         |                         |                        |     |         |          |       |        |        |        |                    |
|                            |             |          | nRAS         | PRE                                                                     | 0                      | 0                       | 1                       | 0                      | 0   | 0       | 00       | 0     | 0      | 0      | 0      | -                  |
|                            |             |          | ...          | repeat pattern 1...4 until nRC - 1, truncate if necessary               |                        |                         |                         |                        |     |         |          |       |        |        |        |                    |
|                            |             |          | 1*nRC+0      | ACT                                                                     | 0                      | 0                       | 1                       | 1                      | 0   | 0       | 00       | 0     | 0      | F      | 0      | -                  |
|                            |             |          | 1*nRC+1,2    | D, D                                                                    | 1                      | 0                       | 0                       | 0                      | 0   | 0       | 00       | 0     | 0      | F      | 0      | -                  |
|                            |             |          | 1*nRC+3,4    | $\overline{\text{D}}, \overline{\text{D}}$                              | 1                      | 1                       | 1                       | 1                      | 0   | 0       | 00       | 0     | 0      | F      | 0      | -                  |
|                            |             |          | ...          | repeat pattern nRC + 1,...4 until nRC + nRCE - 1, truncate if necessary |                        |                         |                         |                        |     |         |          |       |        |        |        |                    |
|                            |             |          | 1*nRC+nRCD   | RD                                                                      | 0                      | 1                       | 0                       | 1                      | 0   | 0       | 00       | 0     | 0      | F      | 0      | 00110011           |
|                            |             |          | ...          | repeat pattern nRC + 1,...4 until nRC + nRAS - 1, truncate if necessary |                        |                         |                         |                        |     |         |          |       |        |        |        |                    |
|                            |             |          | 1*nRC+nRAS   | PRE                                                                     | 0                      | 0                       | 1                       | 0                      | 0   | 0       | 00       | 0     | 0      | F      | 0      | -                  |
|                            |             |          | ...          | repeat pattern nRC + 1,...4 until *2 nRC - 1, truncate if necessary     |                        |                         |                         |                        |     |         |          |       |        |        |        |                    |
|                            |             | 1        | 2*nRC        | repeat Sub-Loop 0, use BA[2:0] = 1 instead                              |                        |                         |                         |                        |     |         |          |       |        |        |        |                    |
|                            |             | 2        | 4*nRC        | repeat Sub-Loop 0, use BA[2:0] = 2 instead                              |                        |                         |                         |                        |     |         |          |       |        |        |        |                    |
|                            |             | 3        | 6*nRC        | repeat Sub-Loop 0, use BA[2:0] = 3 instead                              |                        |                         |                         |                        |     |         |          |       |        |        |        |                    |
|                            |             | 4        | 8*nRC        | repeat Sub-Loop 0, use BA[2:0] = 4 instead                              |                        |                         |                         |                        |     |         |          |       |        |        |        |                    |
|                            |             | 5        | 10*nRC       | repeat Sub-Loop 0, use BA[2:0] = 5 instead                              |                        |                         |                         |                        |     |         |          |       |        |        |        |                    |
|                            |             | 6        | 12*nRC       | repeat Sub-Loop 0, use BA[2:0] = 6 instead                              |                        |                         |                         |                        |     |         |          |       |        |        |        |                    |
|                            |             | 7        | 14*nRC       | repeat Sub-Loop 0, use BA[2:0] = 7 instead                              |                        |                         |                         |                        |     |         |          |       |        |        |        |                    |

a) DM must be driven LOW all the time. DQS,  $\overline{\text{DQS}}$  are used according to RD Commands, otherwise MID-LEVEL.

b) Burst Sequence driven on each DQ signal by Read Command. Outside burst operation, DQ signals are MID\_LEVEL.

**Table 5 - IDD2N and IDD3N Measurement-Loop Pattern<sup>a)</sup>**

| CK, $\overline{\text{CK}}$ | CKE         | Sub-Loop | Cycle Number | Command                                    | $\overline{\text{CS}}$ | $\overline{\text{RAS}}$ | $\overline{\text{CAS}}$ | $\overline{\text{WE}}$ | ODT | BA[2:0] | A[15:11] | A[10] | A[9:7] | A[6:3] | A[2:0] | Data <sup>b)</sup> |
|----------------------------|-------------|----------|--------------|--------------------------------------------|------------------------|-------------------------|-------------------------|------------------------|-----|---------|----------|-------|--------|--------|--------|--------------------|
| toggling                   | Static High | 0        | 0            | D                                          | 1                      | 0                       | 0                       | 0                      | 0   | 0       | 0        | 0     | 0      | 0      | 0      | -                  |
|                            |             |          | 1            | D                                          | 1                      | 0                       | 0                       | 0                      | 0   | 0       | 0        | 0     | 0      | 0      | 0      | -                  |
|                            |             |          | 2            | $\overline{\text{D}}$                      | 1                      | 1                       | 1                       | 1                      | 0   | 0       | 0        | 0     | 0      | F      | 0      | -                  |
|                            |             |          | 3            | $\overline{\text{D}}$                      | 1                      | 1                       | 1                       | 1                      | 0   | 0       | 0        | 0     | 0      | F      | 0      | -                  |
|                            |             | 1        | 4-7          | repeat Sub-Loop 0, use BA[2:0] = 1 instead |                        |                         |                         |                        |     |         |          |       |        |        |        |                    |
|                            |             | 2        | 8-11         | repeat Sub-Loop 0, use BA[2:0] = 2 instead |                        |                         |                         |                        |     |         |          |       |        |        |        |                    |
|                            |             | 3        | 12-15        | repeat Sub-Loop 0, use BA[2:0] = 3 instead |                        |                         |                         |                        |     |         |          |       |        |        |        |                    |
|                            |             | 4        | 16-19        | repeat Sub-Loop 0, use BA[2:0] = 4 instead |                        |                         |                         |                        |     |         |          |       |        |        |        |                    |
|                            |             | 5        | 20-23        | repeat Sub-Loop 0, use BA[2:0] = 5 instead |                        |                         |                         |                        |     |         |          |       |        |        |        |                    |
|                            |             | 6        | 24-17        | repeat Sub-Loop 0, use BA[2:0] = 6 instead |                        |                         |                         |                        |     |         |          |       |        |        |        |                    |
|                            |             | 7        | 28-31        | repeat Sub-Loop 0, use BA[2:0] = 7 instead |                        |                         |                         |                        |     |         |          |       |        |        |        |                    |

a) DM must be driven LOW all the time. DQS,  $\overline{\text{DQS}}$  are MID-LEVEL.

b) DQ signals are MID-LEVEL.

**Table 6 - IDD2NT and IDDQ2NT Measurement-Loop Pattern<sup>a)</sup>**

| CK, $\overline{\text{CK}}$ | CKE         | Sub-Loop | Cycle Number | Command                                        | $\overline{\text{CS}}$ | $\overline{\text{RAS}}$ | $\overline{\text{CAS}}$ | $\overline{\text{WE}}$ | ODT | BA[2:0] | A[15:11] | A[10] | A[9:7] | A[6:3] | A[2:0] | Data <sup>b)</sup> |
|----------------------------|-------------|----------|--------------|------------------------------------------------|------------------------|-------------------------|-------------------------|------------------------|-----|---------|----------|-------|--------|--------|--------|--------------------|
| toggling                   | Static High | 0        | 0            | D                                              | 1                      | 0                       | 0                       | 0                      | 0   | 0       | 0        | 0     | 0      | 0      | 0      | -                  |
|                            |             |          | 1            | D                                              | 1                      | 0                       | 0                       | 0                      | 0   | 0       | 0        | 0     | 0      | 0      | 0      | -                  |
|                            |             |          | 2            | $\overline{\text{D}}$                          | 1                      | 1                       | 1                       | 1                      | 0   | 0       | 0        | 0     | 0      | F      | 0      | -                  |
|                            |             |          | 3            | $\overline{\text{D}}$                          | 1                      | 1                       | 1                       | 1                      | 0   | 0       | 0        | 0     | 0      | F      | 0      | -                  |
|                            |             | 1        | 4-7          | repeat Sub-Loop 0, but ODT = 0 and BA[2:0] = 1 |                        |                         |                         |                        |     |         |          |       |        |        |        |                    |
|                            |             | 2        | 8-11         | repeat Sub-Loop 0, but ODT = 1 and BA[2:0] = 2 |                        |                         |                         |                        |     |         |          |       |        |        |        |                    |
|                            |             | 3        | 12-15        | repeat Sub-Loop 0, but ODT = 1 and BA[2:0] = 3 |                        |                         |                         |                        |     |         |          |       |        |        |        |                    |
|                            |             | 4        | 16-19        | repeat Sub-Loop 0, but ODT = 0 and BA[2:0] = 4 |                        |                         |                         |                        |     |         |          |       |        |        |        |                    |
|                            |             | 5        | 20-23        | repeat Sub-Loop 0, but ODT = 0 and BA[2:0] = 5 |                        |                         |                         |                        |     |         |          |       |        |        |        |                    |
|                            |             | 6        | 24-17        | repeat Sub-Loop 0, but ODT = 1 and BA[2:0] = 6 |                        |                         |                         |                        |     |         |          |       |        |        |        |                    |
|                            |             | 7        | 28-31        | repeat Sub-Loop 0, but ODT = 1 and BA[2:0] = 7 |                        |                         |                         |                        |     |         |          |       |        |        |        |                    |

a) DM must be driven LOW all the time. DQS,  $\overline{\text{DQS}}$  are MID-LEVEL.

b) DQ signals are MID-LEVEL.

**Table 7 - IDD4R and IDDQ4R Measurement-Loop Pattern<sup>a)</sup>**

| CK, CK   | CKE         | Sub-Loop | Cycle Number | Command                            | CS | RAS | CAS | WE | ODT | BA[2:0] | A[15:11] | A[10] | A[9:7] | A[6:3] | A[2:0] | Data <sup>b)</sup> |
|----------|-------------|----------|--------------|------------------------------------|----|-----|-----|----|-----|---------|----------|-------|--------|--------|--------|--------------------|
| toggling | Static High | 0        | 0            | RD                                 | 0  | 1   | 0   | 1  | 0   | 0       | 00       | 0     | 0      | 0      | 0      | 00000000           |
|          |             |          | 1            | D                                  | 1  | 0   | 0   | 0  | 0   | 0       | 00       | 0     | 0      | 0      | 0      | -                  |
|          |             |          | 2,3          | D,D                                | 1  | 1   | 1   | 1  | 0   | 0       | 00       | 0     | 0      | 0      | 0      | -                  |
|          |             |          | 4            | RD                                 | 0  | 1   | 0   | 1  | 0   | 0       | 00       | 0     | 0      | F      | 0      | 00110011           |
|          |             | 5        | 5            | D                                  | 1  | 0   | 0   | 0  | 0   | 0       | 00       | 0     | 0      | F      | 0      | -                  |
|          |             |          | 6,7          | D,D                                | 1  | 1   | 1   | 1  | 0   | 0       | 00       | 0     | 0      | F      | 0      | -                  |
|          |             | 1        | 8-15         | repeat Sub-Loop 0, but BA[2:0] = 1 |    |     |     |    |     |         |          |       |        |        |        |                    |
|          |             | 2        | 16-23        | repeat Sub-Loop 0, but BA[2:0] = 2 |    |     |     |    |     |         |          |       |        |        |        |                    |
|          |             | 3        | 24-31        | repeat Sub-Loop 0, but BA[2:0] = 3 |    |     |     |    |     |         |          |       |        |        |        |                    |
|          |             | 4        | 32-39        | repeat Sub-Loop 0, but BA[2:0] = 4 |    |     |     |    |     |         |          |       |        |        |        |                    |
|          |             | 5        | 40-47        | repeat Sub-Loop 0, but BA[2:0] = 5 |    |     |     |    |     |         |          |       |        |        |        |                    |
|          |             | 6        | 48-55        | repeat Sub-Loop 0, but BA[2:0] = 6 |    |     |     |    |     |         |          |       |        |        |        |                    |
|          |             | 7        | 56-63        | repeat Sub-Loop 0, but BA[2:0] = 7 |    |     |     |    |     |         |          |       |        |        |        |                    |

a) DM must be driven LOW all the time. DQS,  $\overline{DQS}$  are used according to RD Commands, otherwise MID-LEVEL.

b) Burst Sequence driven on each DQ signal by Read Command. Outside burst operation, DQ signals are MID-LEVEL.

**Table 8 - IDD4W Measurement-Loop Pattern<sup>a)</sup>**

| CK, CK   | CKE         | Sub-Loop | Cycle Number | Command                            | CS | RAS | CAS | WE | ODT | BA[2:0] | A[15:11] | A[10] | A[9:7] | A[6:3] | A[2:0] | Data <sup>b)</sup> |
|----------|-------------|----------|--------------|------------------------------------|----|-----|-----|----|-----|---------|----------|-------|--------|--------|--------|--------------------|
| toggling | Static High | 0        | 0            | WR                                 | 0  | 1   | 0   | 0  | 1   | 0       | 00       | 0     | 0      | 0      | 0      | 00000000           |
|          |             |          | 1            | D                                  | 1  | 0   | 0   | 0  | 1   | 0       | 00       | 0     | 0      | 0      | 0      | -                  |
|          |             |          | 2,3          | D,D                                | 1  | 1   | 1   | 1  | 1   | 0       | 00       | 0     | 0      | 0      | 0      | -                  |
|          |             |          | 4            | WR                                 | 0  | 1   | 0   | 0  | 1   | 0       | 00       | 0     | 0      | F      | 0      | 00110011           |
|          |             | 5        | 5            | D                                  | 1  | 0   | 0   | 0  | 1   | 0       | 00       | 0     | 0      | F      | 0      | -                  |
|          |             |          | 6,7          | D,D                                | 1  | 1   | 1   | 1  | 1   | 0       | 00       | 0     | 0      | F      | 0      | -                  |
|          |             | 1        | 8-15         | repeat Sub-Loop 0, but BA[2:0] = 1 |    |     |     |    |     |         |          |       |        |        |        |                    |
|          |             | 2        | 16-23        | repeat Sub-Loop 0, but BA[2:0] = 2 |    |     |     |    |     |         |          |       |        |        |        |                    |
|          |             | 3        | 24-31        | repeat Sub-Loop 0, but BA[2:0] = 3 |    |     |     |    |     |         |          |       |        |        |        |                    |
|          |             | 4        | 32-39        | repeat Sub-Loop 0, but BA[2:0] = 4 |    |     |     |    |     |         |          |       |        |        |        |                    |
|          |             | 5        | 40-47        | repeat Sub-Loop 0, but BA[2:0] = 5 |    |     |     |    |     |         |          |       |        |        |        |                    |
|          |             | 6        | 48-55        | repeat Sub-Loop 0, but BA[2:0] = 6 |    |     |     |    |     |         |          |       |        |        |        |                    |
|          |             | 7        | 56-63        | repeat Sub-Loop 0, but BA[2:0] = 7 |    |     |     |    |     |         |          |       |        |        |        |                    |

a) DM must be driven LOW all the time. DQS,  $\overline{DQS}$  are used according to WR Commands, otherwise MID-LEVEL.

b) Burst Sequence driven on each DQ signal by Write Command. Outside burst operation, DQ signals are MID-LEVEL.

**Table 9 - IDD5B Measurement-Loop Pattern<sup>a)</sup>**

| CK, $\overline{\text{CK}}$ | CKE         | Sub-Loop | Cycle Number | Command                                                    | $\overline{\text{CS}}$ | $\overline{\text{RAS}}$ | $\overline{\text{CAS}}$ | $\overline{\text{WE}}$ | ODT | BA[2:0] | A[15:11] | A[10] | A[9:7] | A[6:3] | A[2:0] | Data <sup>b)</sup> |
|----------------------------|-------------|----------|--------------|------------------------------------------------------------|------------------------|-------------------------|-------------------------|------------------------|-----|---------|----------|-------|--------|--------|--------|--------------------|
| toggling                   | Static High | 0        | 0            | REF                                                        | 0                      | 0                       | 0                       | 1                      | 0   | 0       | 0        | 0     | 0      | 0      | 0      | -                  |
|                            |             | 1        | 1.2          | D, D                                                       | 1                      | 0                       | 0                       | 0                      | 0   | 0       | 00       | 0     | 0      | 0      | 0      | -                  |
|                            |             |          | 3,4          | $\overline{\text{D}}$ , $\overline{\text{D}}$              | 1                      | 1                       | 1                       | 1                      | 0   | 0       | 00       | 0     | 0      | F      | 0      | -                  |
|                            |             |          | 5...8        | repeat cycles 1...4, but BA[2:0] = 1                       |                        |                         |                         |                        |     |         |          |       |        |        |        |                    |
|                            |             |          | 9...12       | repeat cycles 1...4, but BA[2:0] = 2                       |                        |                         |                         |                        |     |         |          |       |        |        |        |                    |
|                            |             |          | 13...16      | repeat cycles 1...4, but BA[2:0] = 3                       |                        |                         |                         |                        |     |         |          |       |        |        |        |                    |
|                            |             |          | 17...20      | repeat cycles 1...4, but BA[2:0] = 4                       |                        |                         |                         |                        |     |         |          |       |        |        |        |                    |
|                            |             |          | 21...24      | repeat cycles 1...4, but BA[2:0] = 5                       |                        |                         |                         |                        |     |         |          |       |        |        |        |                    |
|                            |             |          | 25...28      | repeat cycles 1...4, but BA[2:0] = 6                       |                        |                         |                         |                        |     |         |          |       |        |        |        |                    |
|                            |             |          | 29...32      | repeat cycles 1...4, but BA[2:0] = 7                       |                        |                         |                         |                        |     |         |          |       |        |        |        |                    |
|                            |             | 2        | 33...nRFC-1  | repeat Sub-Loop 1, until nRFC - 1. Truncate, if necessary. |                        |                         |                         |                        |     |         |          |       |        |        |        |                    |

a) DM must be driven LOW all the time. DQS,  $\overline{\text{DQS}}$  are MID-LEVEL.

b) DQ signals are MID-LEVEL.

**Table 10 - IDD7 Measurement-Loop Pattern<sup>a)</sup>**
**ATTENTION! Sub-Loops 10-19 have inverse A[6:3] Pattern and Data Pattern than Sub-Loops 0-9**

| CK, CK   | CKE         | Sub-Loop | Cycle Number  | Command                                                           | $\overline{CS}$ | $\overline{RAS}$ | $\overline{CAS}$ | $\overline{WE}$ | ODT | BA[2:0] | A[15:11] | A[10] | A[9:7] | A[6:3] | A[2:0] | Data <sup>b)</sup> |
|----------|-------------|----------|---------------|-------------------------------------------------------------------|-----------------|------------------|------------------|-----------------|-----|---------|----------|-------|--------|--------|--------|--------------------|
| toggling | Static High | 0        | 0             | ACT                                                               | 0               | 0                | 1                | 1               | 0   | 0       | 00       | 0     | 0      | 0      | 0      | -                  |
|          |             |          | 1             | RDA                                                               | 0               | 1                | 0                | 1               | 0   | 0       | 00       | 1     | 0      | 0      | 0      | 00000000           |
|          |             |          | 2             | D                                                                 | 1               | 0                | 0                | 0               | 0   | 0       | 00       | 0     | 0      | 0      | 0      | -                  |
|          |             |          | ...           | repeat above D Command until nRRD - 1                             |                 |                  |                  |                 |     |         |          |       |        |        |        |                    |
|          |             | 1        | nRRD          | ACT                                                               | 0               | 0                | 1                | 1               | 0   | 1       | 00       | 0     | 0      | F      | 0      | -                  |
|          |             |          | nRRD+1        | RDA                                                               | 0               | 1                | 0                | 1               | 0   | 1       | 00       | 1     | 0      | F      | 0      | 00110011           |
|          |             |          | nRRD+2        | D                                                                 | 1               | 0                | 0                | 0               | 0   | 1       | 00       | 0     | 0      | F      | 0      | -                  |
|          |             |          | ...           | repeat above D Command until 2* nRRD - 1                          |                 |                  |                  |                 |     |         |          |       |        |        |        |                    |
|          |             | 2        | 2*nRRD        | repeat Sub-Loop 0, but BA[2:0] = 2                                |                 |                  |                  |                 |     |         |          |       |        |        |        |                    |
|          |             | 3        | 3*nRRD        | repeat Sub-Loop 1, but BA[2:0] = 3                                |                 |                  |                  |                 |     |         |          |       |        |        |        |                    |
|          |             | 4        | 4*nRRD        | D                                                                 | 1               | 0                | 0                | 0               | 0   | 3       | 00       | 0     | 0      | F      | 0      | -                  |
|          |             |          |               | Assert and repeat above D Command until nFAW - 1, if necessary    |                 |                  |                  |                 |     |         |          |       |        |        |        |                    |
|          |             | 5        | nFAW          | repeat Sub-Loop 0, but BA[2:0] = 4                                |                 |                  |                  |                 |     |         |          |       |        |        |        |                    |
|          |             | 6        | nFAW+nRRD     | repeat Sub-Loop 1, but BA[2:0] = 5                                |                 |                  |                  |                 |     |         |          |       |        |        |        |                    |
|          |             | 7        | nFAW+2*nRRD   | repeat Sub-Loop 0, but BA[2:0] = 6                                |                 |                  |                  |                 |     |         |          |       |        |        |        |                    |
|          |             | 8        | nFAW+3*nRRD   | repeat Sub-Loop 1, but BA[2:0] = 7                                |                 |                  |                  |                 |     |         |          |       |        |        |        |                    |
|          |             | 9        | nFAW+4*nRRD   | D                                                                 | 1               | 0                | 0                | 0               | 0   | 7       | 00       | 0     | 0      | F      | 0      | -                  |
|          |             |          |               | Assert and repeat above D Command until 2* nFAW - 1, if necessary |                 |                  |                  |                 |     |         |          |       |        |        |        |                    |
|          |             | 10       | 2*nFAW+0      | ACT                                                               | 0               | 0                | 1                | 1               | 0   | 0       | 00       | 0     | 0      | F      | 0      | -                  |
|          |             |          | 2*nFAW+1      | RDA                                                               | 0               | 1                | 0                | 1               | 0   | 0       | 00       | 1     | 0      | F      | 0      | 00110011           |
|          |             |          | 2&nFAW+2      | D                                                                 | 1               | 0                | 0                | 0               | 0   | 0       | 00       | 0     | 0      | F      | 0      | -                  |
|          |             |          |               | Repeat above D Command until 2* nFAW + nRRD - 1                   |                 |                  |                  |                 |     |         |          |       |        |        |        |                    |
|          |             | 11       | 2*nFAW+nRRD   | ACT                                                               | 0               | 0                | 1                | 1               | 0   | 1       | 00       | 0     | 0      | 0      | 0      | -                  |
|          |             |          | 2*nFAW+nRRD+1 | RDA                                                               | 0               | 1                | 0                | 1               | 0   | 1       | 00       | 1     | 0      | 0      | 0      | 00000000           |
|          |             |          | 2&nFAW+nRRD+2 | D                                                                 | 1               | 0                | 0                | 0               | 0   | 1       | 00       | 0     | 0      | 0      | 0      | -                  |
|          |             |          |               | Repeat above D Command until 2* nFAW + 2* nRRD - 1                |                 |                  |                  |                 |     |         |          |       |        |        |        |                    |
|          |             | 12       | 2*nFAW+2*nRRD | repeat Sub-Loop 10, but BA[2:0] = 2                               |                 |                  |                  |                 |     |         |          |       |        |        |        |                    |
|          |             | 13       | 2*nFAW+3*nRRD | repeat Sub-Loop 11, but BA[2:0] = 3                               |                 |                  |                  |                 |     |         |          |       |        |        |        |                    |
|          |             | 14       | 2*nFAW+4*nRRD | D                                                                 | 1               | 0                | 0                | 0               | 0   | 3       | 00       | 0     | 0      | 0      | 0      | -                  |
|          |             |          |               | Assert and repeat above D Command until 3* nFAW - 1, if necessary |                 |                  |                  |                 |     |         |          |       |        |        |        |                    |
|          |             | 15       | 3*nFAW        | repeat Sub-Loop 10, but BA[2:0] = 4                               |                 |                  |                  |                 |     |         |          |       |        |        |        |                    |
|          |             | 16       | 3*nFAW+nRRD   | repeat Sub-Loop 11, but BA[2:0] = 5                               |                 |                  |                  |                 |     |         |          |       |        |        |        |                    |
|          |             | 17       | 3*nFAW+2*nRRD | repeat Sub-Loop 10, but BA[2:0] = 6                               |                 |                  |                  |                 |     |         |          |       |        |        |        |                    |
|          |             | 18       | 3*nFAW+3*nRRD | repeat Sub-Loop 11, but BA[2:0] = 7                               |                 |                  |                  |                 |     |         |          |       |        |        |        |                    |
|          |             | 19       | 3*nFAW+4*nRRD | D                                                                 | 1               | 0                | 0                | 0               | 0   | 7       | 00       | 0     | 0      | 0      | 0      | -                  |
|          |             |          |               | Assert and repeat above D Command until 4* nFAW - 1, if necessary |                 |                  |                  |                 |     |         |          |       |        |        |        |                    |

a) DM must be driven LOW all the time. DQS,  $\overline{DQS}$  are used according to RD Commands, otherwise MID-LEVEL.

b) Burst Sequence driven on each DQ signal by Read Command. Outside burst operation, DQ signals are MID-LEVEL.

## IDD Specifications (Tcase: 0 to 95°C)

\* Module IDD values in the datasheet are only a calculation based on the component IDD spec.  
The actual measurements may vary according to DQ loading cap.

### 2GB, 256M x 64 SO-DIMM: HMT425S6AFR6A

| Symbol | DDR3L 1066 | DDR3L 1333 | DDR3L 1600 | DDR3L 1866 | Unit | note |
|--------|------------|------------|------------|------------|------|------|
| IDD0   | 164        | 168        | 172        | 176        | mA   |      |
| IDD1   | 204        | 212        | 212        | 216        | mA   |      |
| IDD2N  | 80         | 80         | 88         | 92         | mA   |      |
| IDD2NT | 92         | 96         | 108        | 116        | mA   |      |
| IDD2P0 | 48         | 48         | 48         | 52         | mA   |      |
| IDD2P1 | 56         | 56         | 56         | 60         | mA   |      |
| IDD2Q  | 80         | 84         | 92         | 96         | mA   |      |
| IDD3N  | 104        | 108        | 116        | 116        | mA   |      |
| IDD3P  | 72         | 72         | 76         | 80         | mA   |      |
| IDD4R  | 360        | 440        | 500        | 560        | mA   |      |
| IDD4W  | 400        | 480        | 540        | 620        | mA   |      |
| IDD5B  | 800        | 800        | 800        | 800        | mA   |      |
| IDD6   | 60         | 60         | 60         | 60         | mA   |      |
| IDD6ET | 72         | 72         | 72         | 72         | mA   |      |
| IDD7   | 680        | 780        | 800        | 820        | mA   |      |

### 4GB, 512M x 64 SO-DIMM: HMT451S6AFR6A

| Symbol | DDR3L 1066 | DDR3L 1333 | DDR3L 1600 | DDR3L 1866 | Unit | note |
|--------|------------|------------|------------|------------|------|------|
| IDD0   | 244        | 248        | 288        | 292        | mA   |      |
| IDD1   | 284        | 292        | 328        | 332        | mA   |      |
| IDD2N  | 160        | 160        | 176        | 184        | mA   |      |
| IDD2NT | 184        | 192        | 216        | 232        | mA   |      |
| IDD2P0 | 96         | 96         | 96         | 104        | mA   |      |
| IDD2P1 | 112        | 112        | 112        | 120        | mA   |      |
| IDD2Q  | 160        | 168        | 184        | 192        | mA   |      |
| IDD3N  | 208        | 216        | 232        | 232        | mA   |      |
| IDD3P  | 144        | 144        | 152        | 160        | mA   |      |
| IDD4R  | 440        | 520        | 616        | 676        | mA   |      |
| IDD4W  | 480        | 560        | 656        | 736        | mA   |      |
| IDD5B  | 880        | 880        | 916        | 916        | mA   |      |
| IDD6   | 120        | 120        | 120        | 120        | mA   |      |
| IDD6ET | 144        | 144        | 144        | 144        | mA   |      |
| IDD7   | 760        | 860        | 916        | 936        | mA   |      |

## 4GB, 512M x 64 SO-DIMM: HMT451S6AFR8A

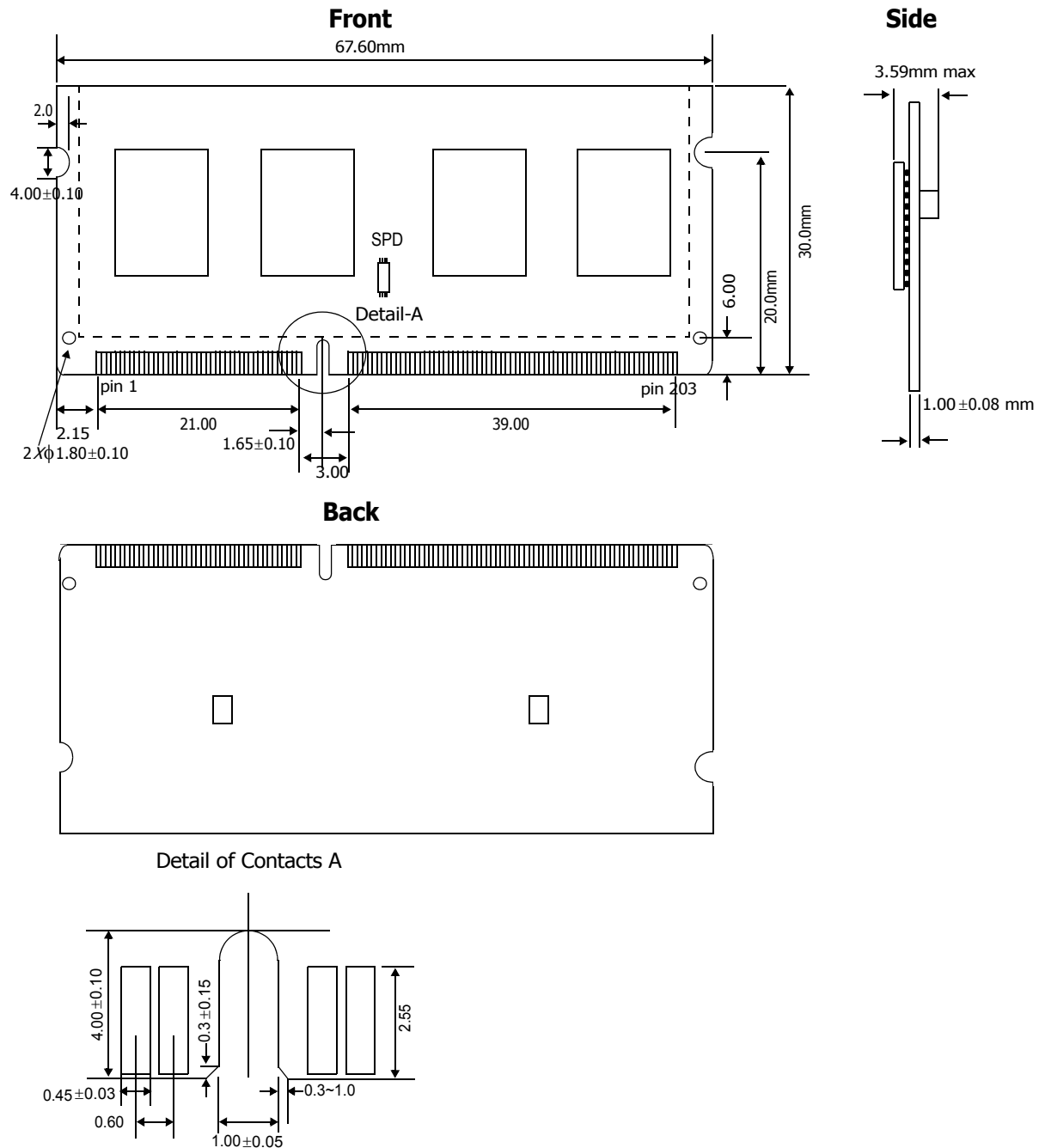
| Symbol | DDR3L 1066 | DDR3L 1333 | DDR3L 1600 | DDR3L 1866 | Unit | note |
|--------|------------|------------|------------|------------|------|------|
| IDD0   | 240        | 256        | 264        | 272        | mA   |      |
| IDD1   | 296        | 312        | 320        | 328        | mA   |      |
| IDD2N  | 120        | 128        | 136        | 144        | mA   |      |
| IDD2NT | 144        | 160        | 168        | 176        | mA   |      |
| IDD2P0 | 64         | 64         | 64         | 64         | mA   |      |
| IDD2P1 | 72         | 80         | 80         | 88         | mA   |      |
| IDD2Q  | 128        | 136        | 136        | 136        | mA   |      |
| IDD3N  | 192        | 200        | 208        | 216        | mA   |      |
| IDD3P  | 136        | 136        | 144        | 144        | mA   |      |
| IDD4R  | 520        | 600        | 680        | 760        | mA   |      |
| IDD4W  | 560        | 640        | 720        | 800        | mA   |      |
| IDD5B  | 1600       | 1600       | 1600       | 1600       | mA   |      |
| IDD6   | 96         | 96         | 96         | 96         | mA   |      |
| IDD6ET | 128        | 128        | 128        | 128        | mA   |      |
| IDD7   | 880        | 1040       | 1080       | 1160       | mA   |      |

## 8GB, 1G x 64 SO-DIMM: HMT41GS6AFR8A

| Symbol | DDR3L 1066 | DDR3L 1333 | DDR3L 1600 | DDR3L 1866 | Unit | note |
|--------|------------|------------|------------|------------|------|------|
| IDD0   | 360        | 384        | 472        | 488        | mA   |      |
| IDD1   | 416        | 440        | 528        | 544        | mA   |      |
| IDD2N  | 240        | 256        | 272        | 288        | mA   |      |
| IDD2NT | 288        | 320        | 336        | 352        | mA   |      |
| IDD2P0 | 128        | 128        | 128        | 128        | mA   |      |
| IDD2P1 | 144        | 160        | 160        | 176        | mA   |      |
| IDD2Q  | 256        | 272        | 272        | 272        | mA   |      |
| IDD3N  | 384        | 400        | 416        | 432        | mA   |      |
| IDD3P  | 272        | 272        | 288        | 288        | mA   |      |
| IDD4R  | 640        | 728        | 888        | 976        | mA   |      |
| IDD4W  | 680        | 768        | 928        | 1016       | mA   |      |
| IDD5B  | 1720       | 1728       | 1808       | 1816       | mA   |      |
| IDD6   | 192        | 192        | 192        | 192        | mA   |      |
| IDD6ET | 256        | 256        | 256        | 256        | mA   |      |
| IDD7   | 1000       | 1168       | 1288       | 1376       | mA   |      |

## Module Dimensions

## 256Mx64 - HMT425S6AFR6A

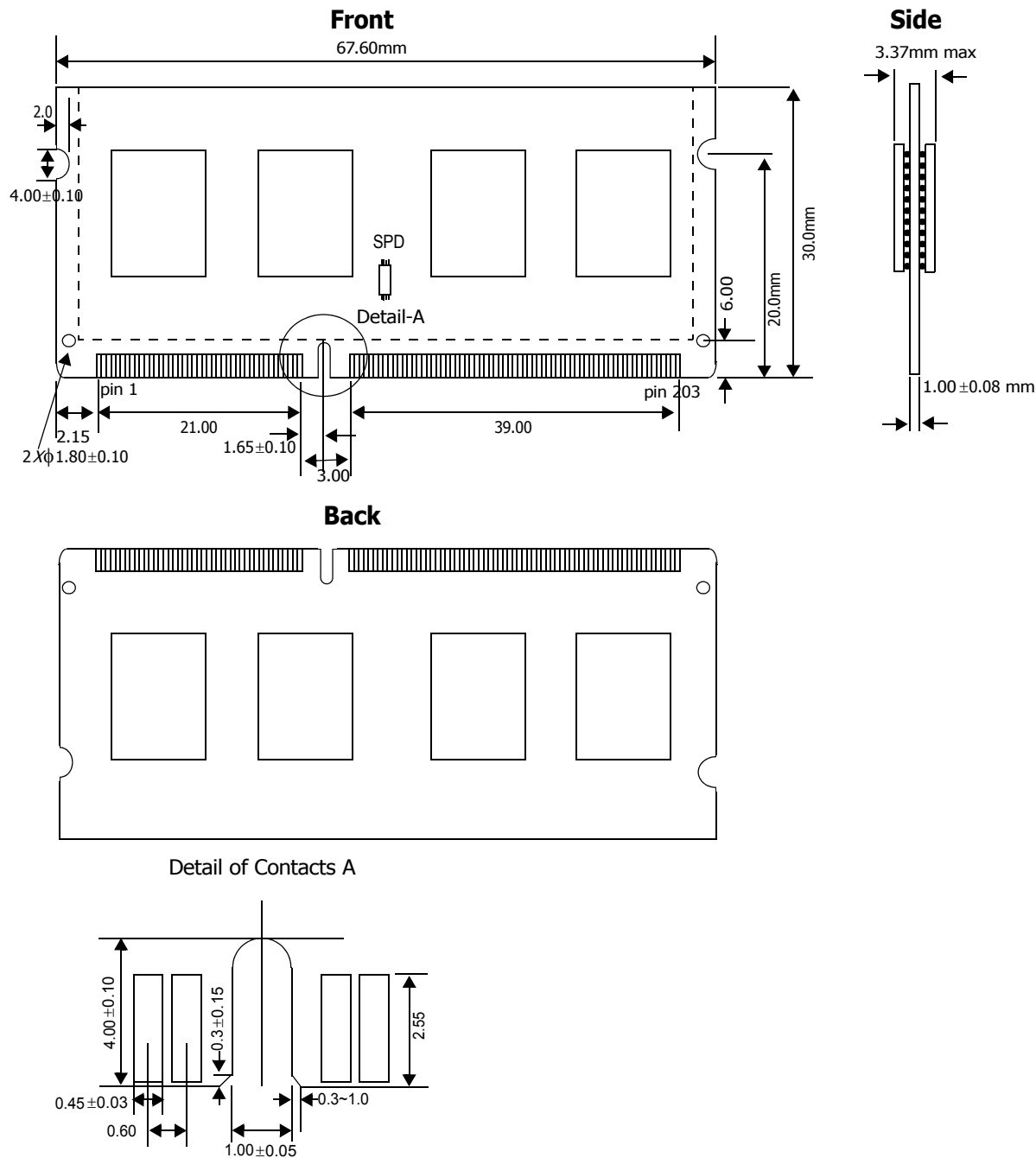


**Note:**

1.  $\pm 0.13$  tolerance on all dimensions unless otherwise stated.

**Units: millimeters**

## 512Mx64 - HMT451S6AFR6A

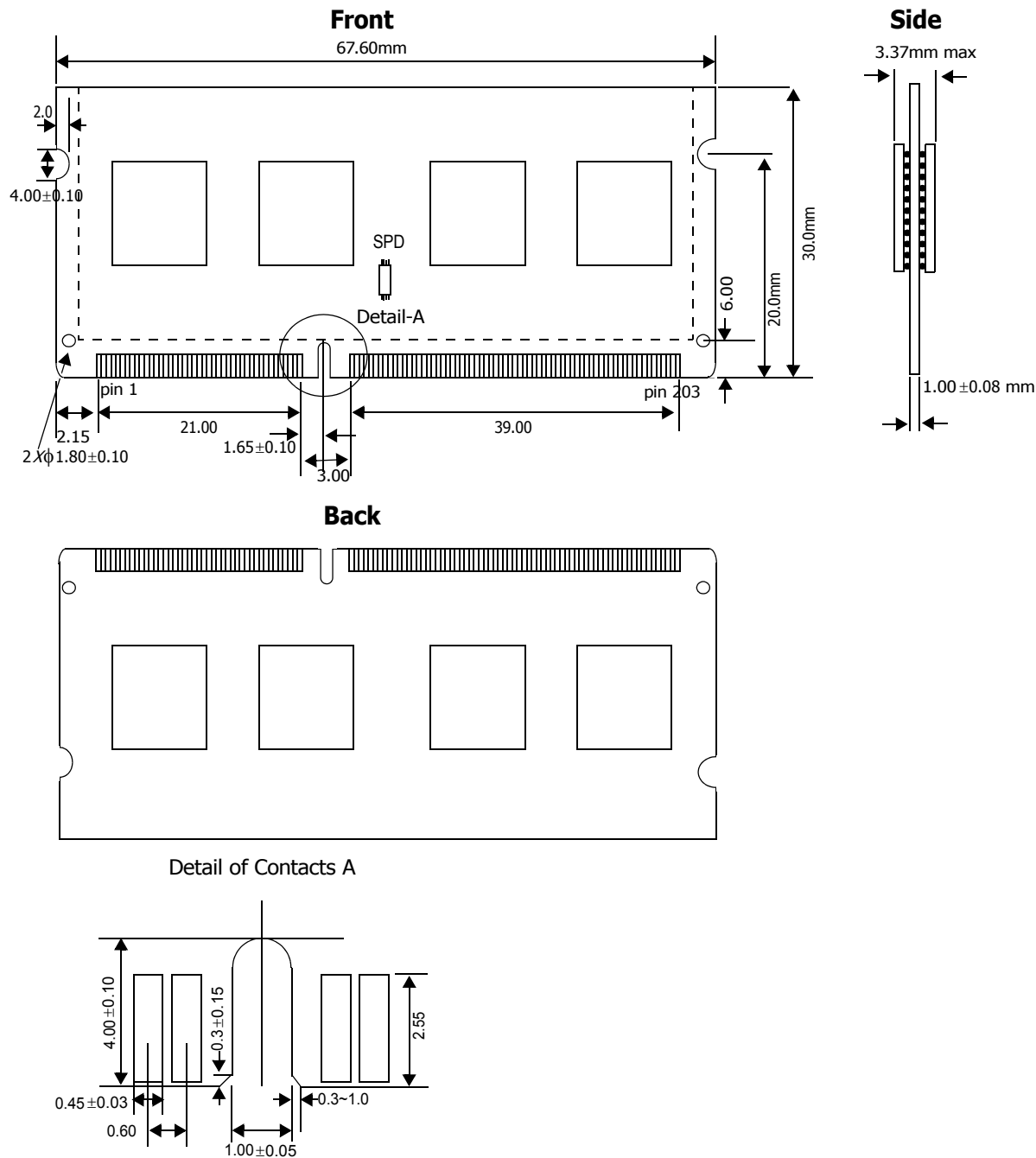


### Note:

1. ±0.13 tolerance on all dimensions unless otherwise stated.

**Units: millimeters**

## 512Mx64 - HMT451S6AFR8A

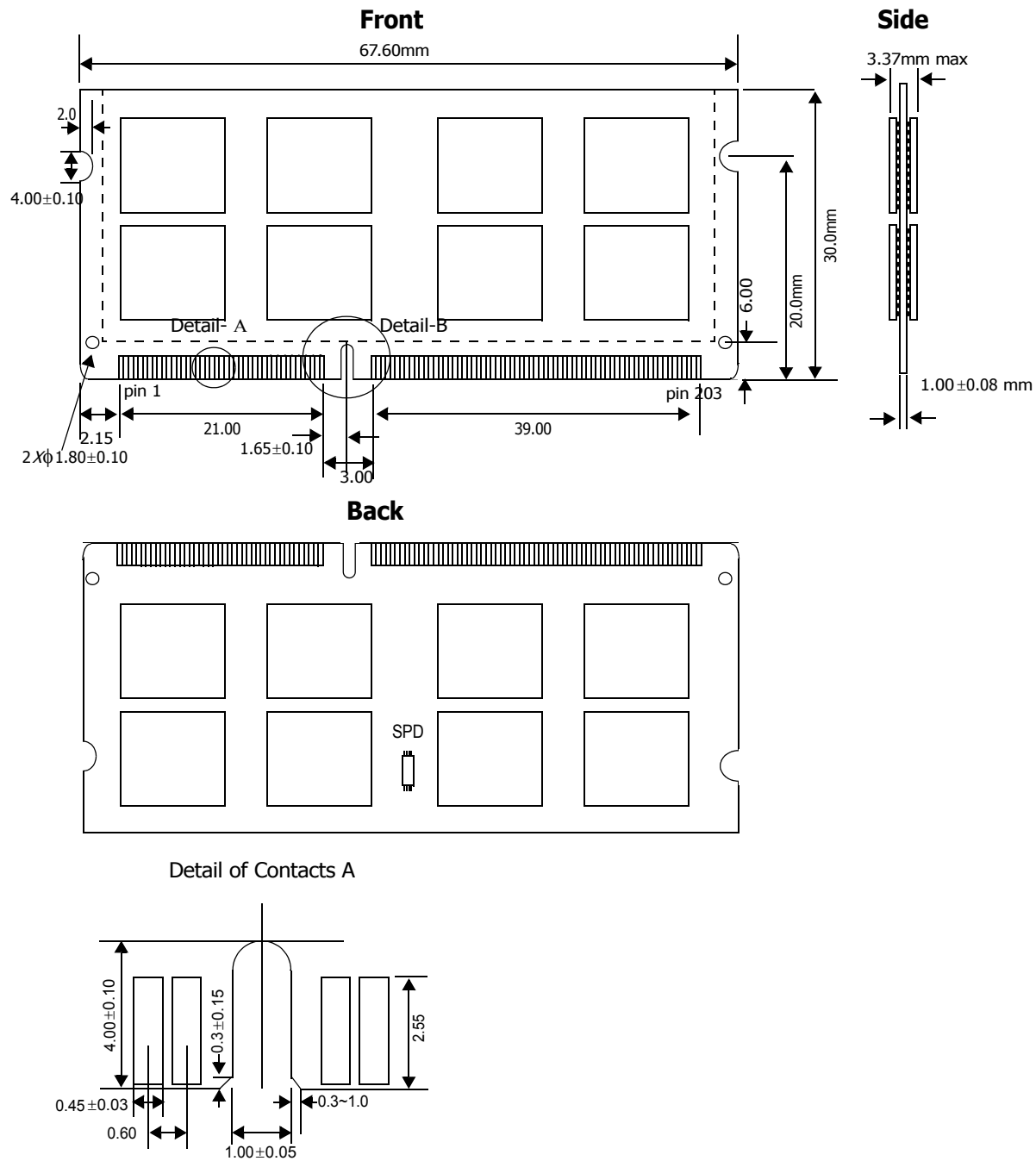


### Note:

1. ±0.13 tolerance on all dimensions unless otherwise stated.

**Units: millimeters**

# 1Gx64 - HMT41GS6AFR8A



## Note:

1. ±0.13 tolerance on all dimensions unless otherwise stated.

**Units: millimeters**